

Status and perspectives of SiPMs for Big Physics Experiments at FBK

Alberto Gola Chief Scientist

F. Acerbi, A. Ficorella, S. Merzi, O. Marti Villareal, E.Moretti, L. Parellada Monreal, G. Paternoster, M. Penna, M. Ruzzarin, N. Zorzi

gola@fbk.eu

Fondazione Bruno Kessler Custom Silicon Detectors



Detector-grade clean-room, 6 inches, class 10 and 100



SiPMs, LGADs, pixel and 3D detectors account for a significant portion of the detectors fabricated here.

FBK is typically interested in R&D activities and collaborations to <u>improve and</u> <u>customize detector technologies for specific applications</u>.

Large area productions can be carried out in FBK (up to ~5 sqm) or relying on external partners (low cost): success stories of technology transfers.



Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023



Private Research Foundation

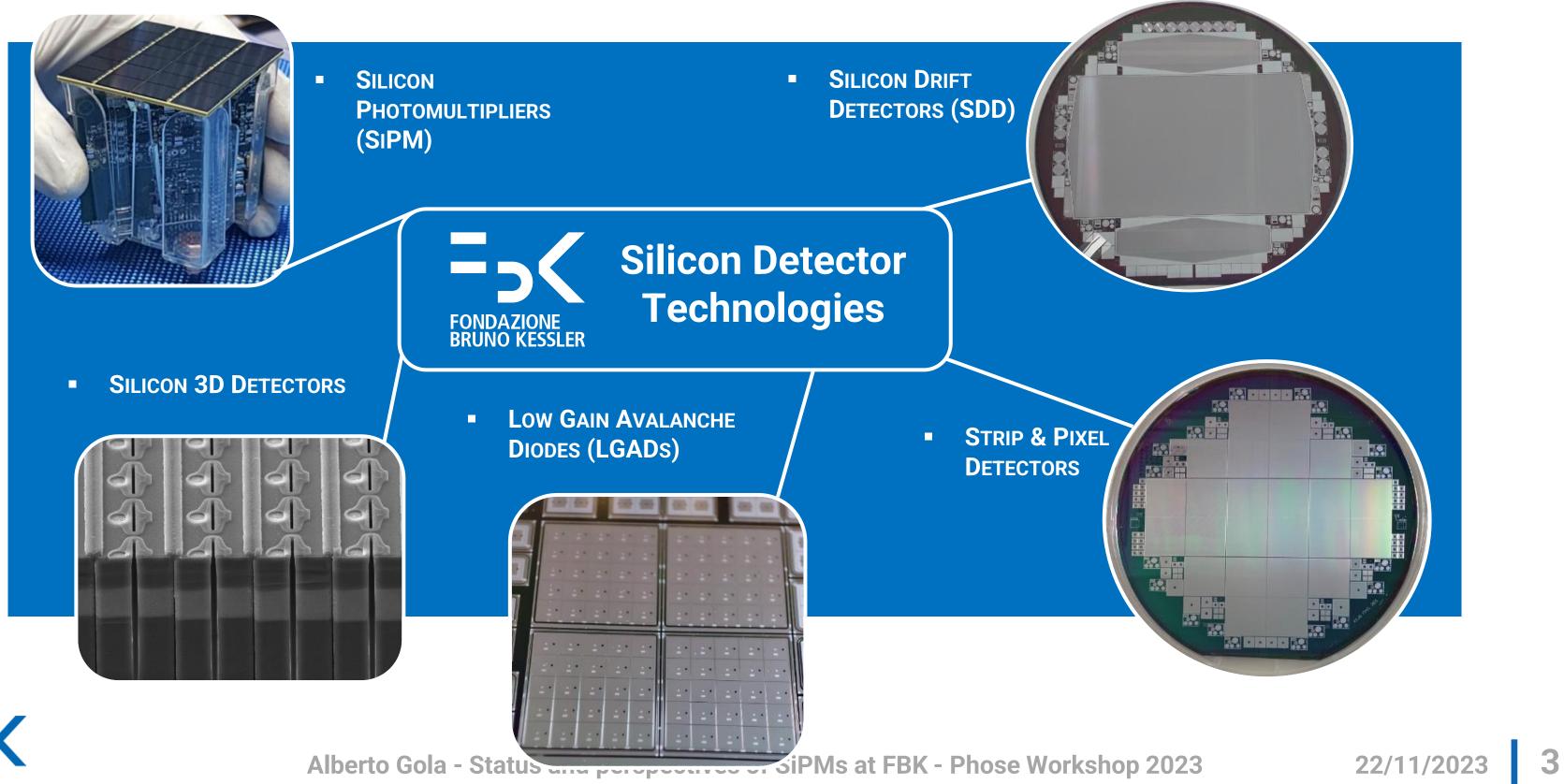
- ~400 researchers in different fields, ranging from Microelectronics to Information Technology
- 50% funding from local government
- 50% self-funding rate
 - 25% from publicly funded research
 - 25% from collaboration with companies





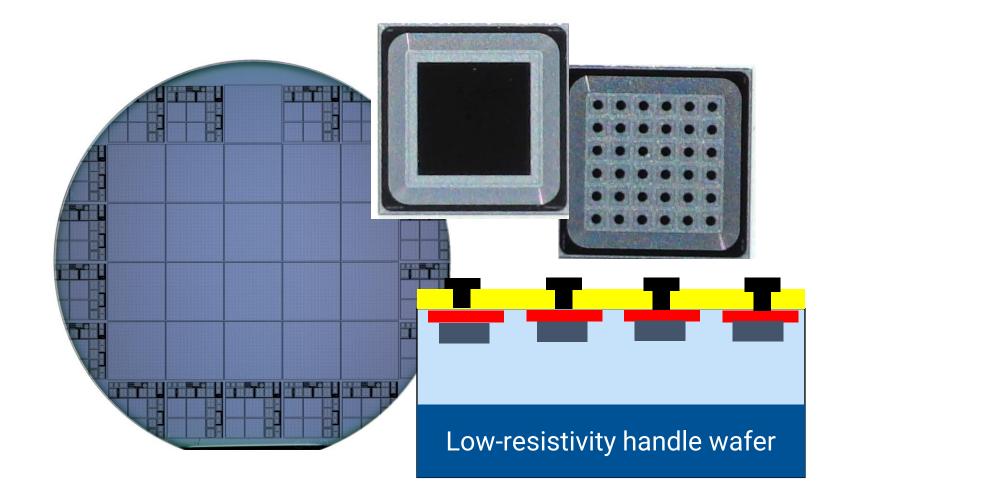


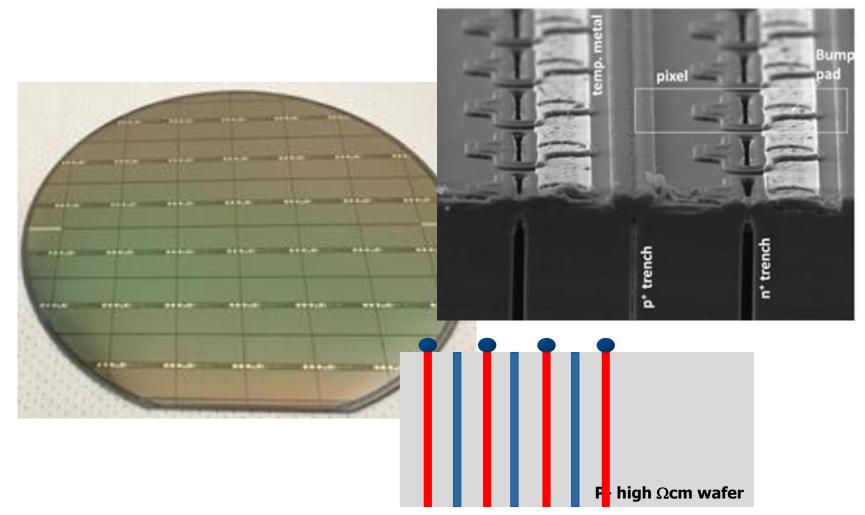
FBK Silicon Detector Technologies Different types of detectors



FBK Silicon Detector Technologies Detectors for 4d-Tracking in HL-LHC

Low Gain Avalanche Diode - LGAD





- Detectors with "low" internal gain ٠
- High time resolution down to 30 ps ullet
- High radiation hardness up to 2e15 neq/cm²
- Under qualification for CMS-ETL and ATLAS-HGTD

Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

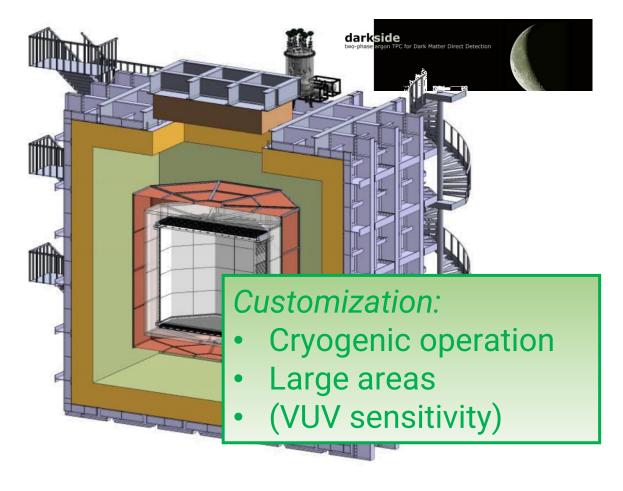
3D Detectors – 3DD

Detectors with columnar vertical junction High time resolution down to 20 ps High radiation hardness up to 1e16 neq/cm² In production for HL-LHC CMS and ATALS

FBK SiPM technologies Use in Big Physics Experiments

Thanks to constant performance improvement, SiPM technologies are now used in several upgrades of Big Physics Experiments: *deep customization is often required*.







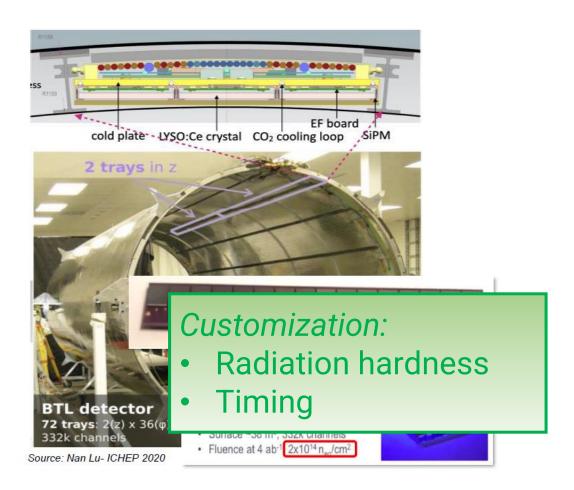


Cryogenic SiPMs will be employed in experiments such as DarkSide-20k

Prototype pSCT installed in the VERITAS, equipped with FBK SiPMs.







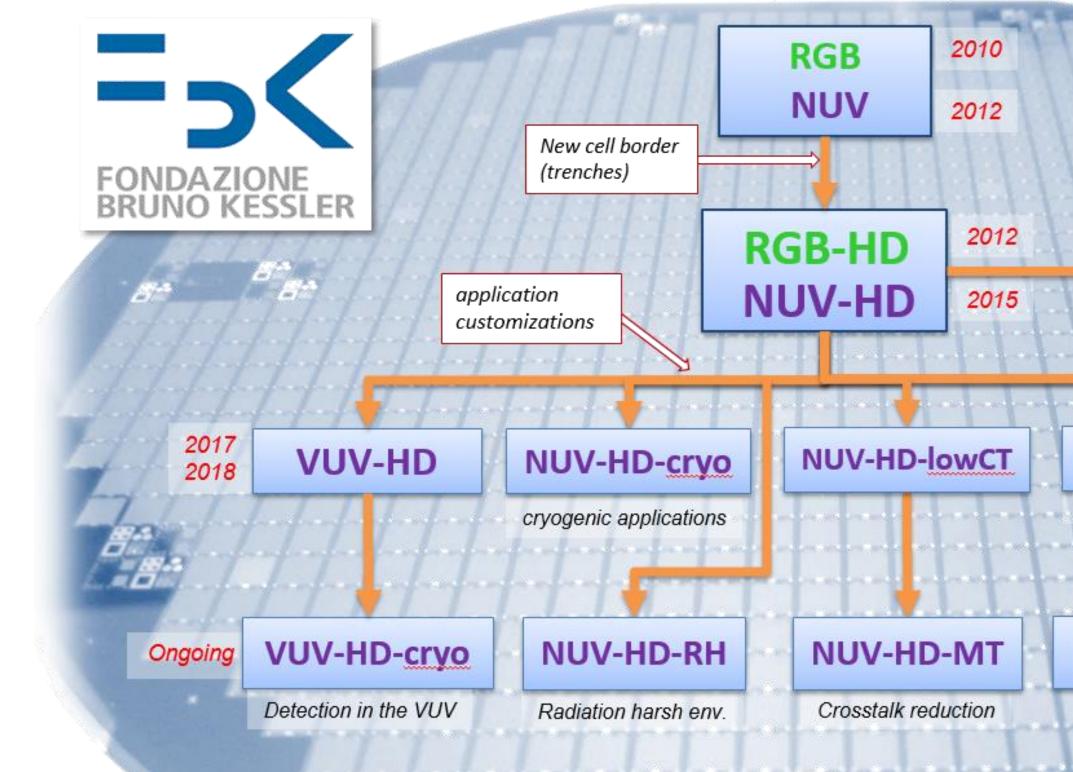
NUV-HD SiPMs are being evaluated for the MIP timing detector of CMS (LYSO scintillator readout).

22/11/2023

5



Fondazione Bruno Kessler Custom SiPM technology roadmap



=5<

Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

LG-SiPMs

position-sensitivity

RGB-UHD

NIR-HD

Very small cell pitch

NIR-UHD

NIR-HD-BSI

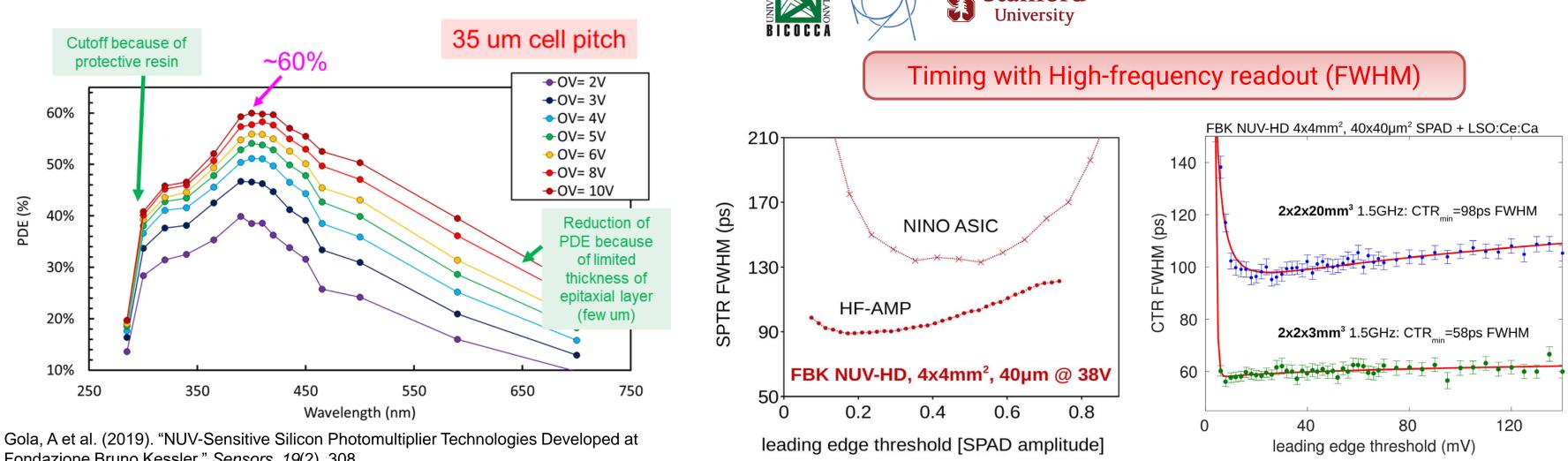
Novel structures for NIR detection

22/11/2023

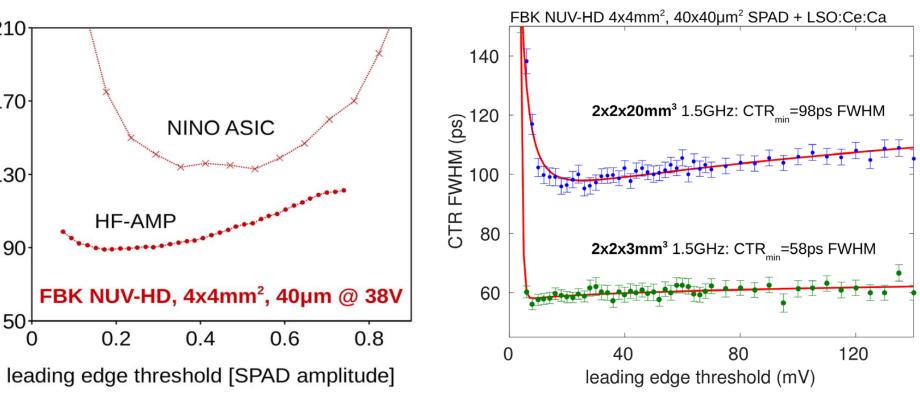
6

FBK SiPM technologies NUV-HD SiPM technology

NUV-HD SiPMs provide *state-of-the-art performance* for single photon detection, timing and for scintillation light readout.

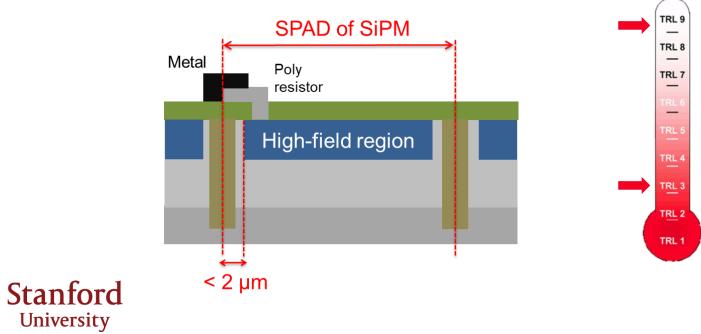


Fondazione Bruno Kessler." Sensors, 19(2), 308.



LYSO readout (right).

Gundacker, Stefan, et al. "High-frequency SiPM readout advances measured coincidence time resolution limits in TOF-PET." Physics in Medicine & Biology 64.5 (2019): 055012.



World record timing resolution: Single Photon Time resolution (SPTR, left) and Coincidence Resolving Time (CRT) in

Improvement of Timing Performance



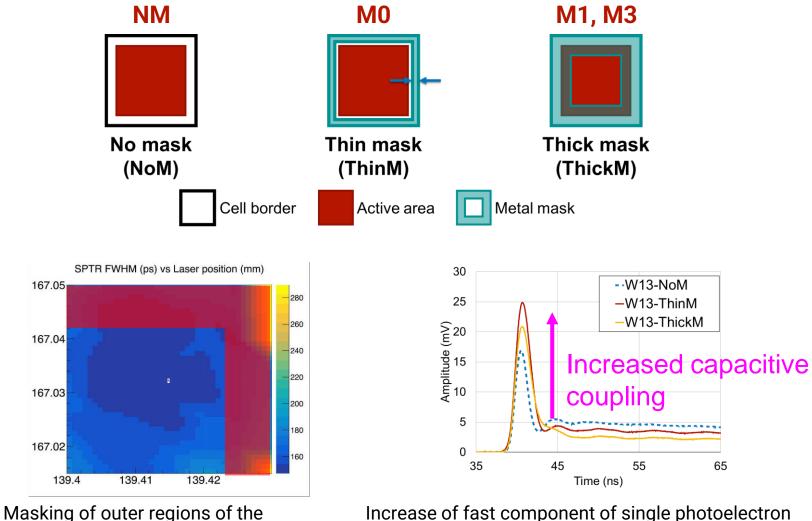
Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

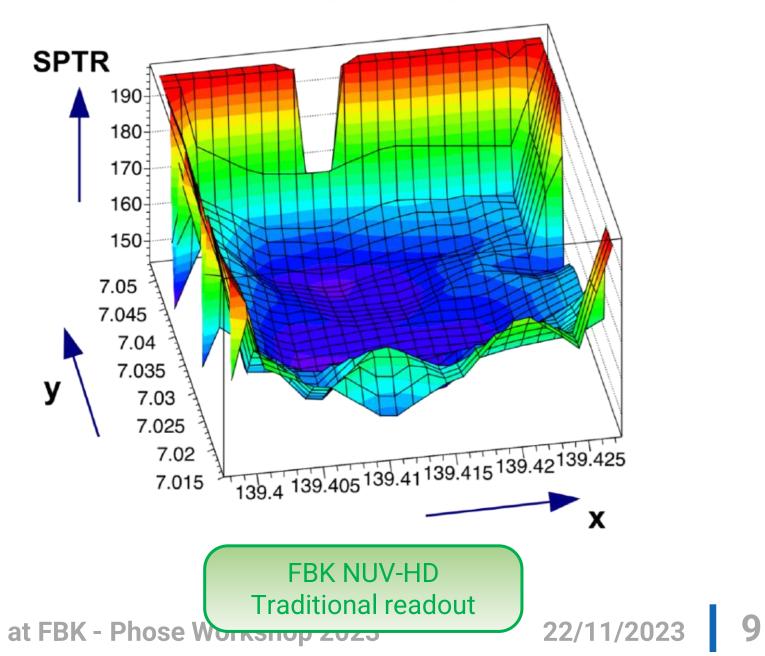


Masking **Optimization of SPTR with masking: CHK-HD**

CHK-HD SiPMs is a variant of the NUV-HD SiPMs built to experiment solutions to improve SPTR and detection efficiency in applications where it matters the most, such as Cherenkov light readout.

- Masking of outer regions of SPAD: Improve signal peaking and mask areas of SPAD with worse SPTR
- Changes to the *Electric field*: low-field + different spectral response





Increase of fast component of single photoelectron signal in accordance with masking extension.



SPAD that have worse "local" SPTR.

Nemallapudi, M. V., et al. "Single photon time resolution of state of the art SiPMs." Journal of Instrumentation 11.10 (2016) SP10016. and perspectives of SiPMs at FBK - Phose Workshop 2023

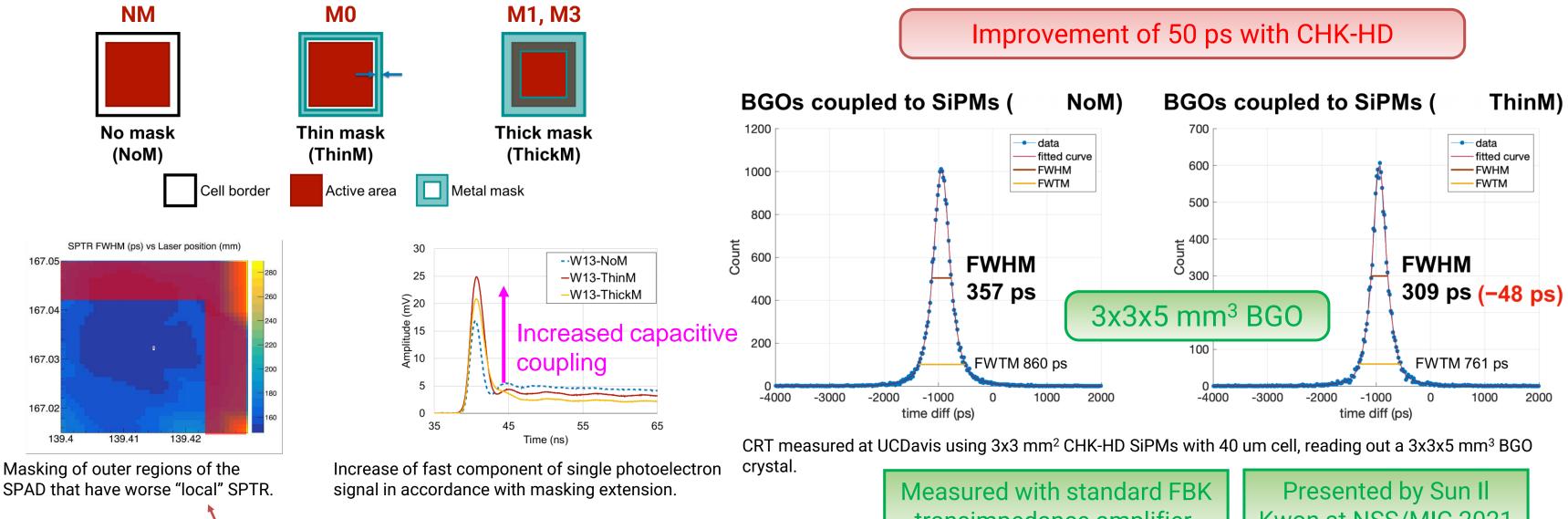


SPTR FWHM (ps) vs Laser position (mm)

Masking **Optimization of SPTR with masking: CHK-HD**

CHK-HD SiPMs is a variant of the NUV-HD SiPMs built to experiment solutions to improve SPTR and detection efficiency in applications where it matters the most, such as Cherenkov light readout.

- Masking of outer regions of SPAD: Improve signal peaking and mask areas of SPAD with worse SPTR
- Changes to the *Electric field*: low-field + different spectral response



Nemallapudi, M. V., et al. "Single photon time resolution of state of the art SiPMs." Journal of Instrumentation 11.100 (2016) SP10016. and perspectives of SiPMs at FBK - Phose Workshop 2023



transimpedance amplifier.

Kwon at NSS/MIC 2021

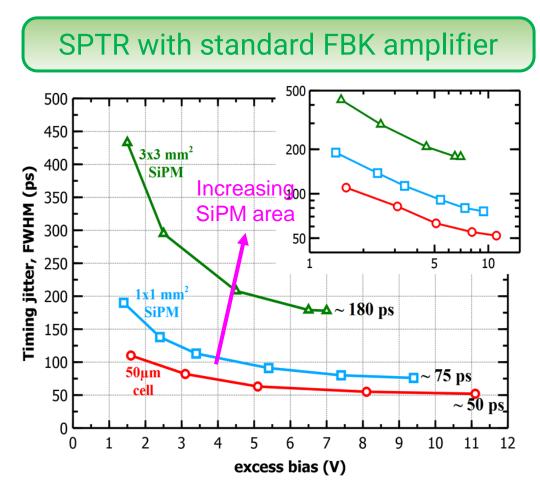
22/11/2023

10

Timing performance Effect of SiPM area on SPTR

SPTR and CRT performance is degraded when reading out SiPMs with large areas.

A possible solution can be the segmentation of the active area into small pixels, with separate readout, followed by signal summation or combination of time pick-off information.



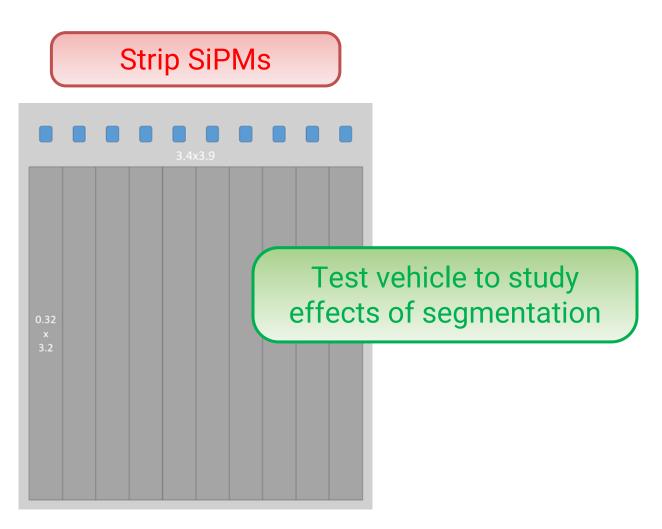


SPTR vs. excess bias for different SiPM sizes, with traditional amplifier.



Acerbi, Fabio, et al. "Characterization of single-photon time resolution: from single SPAD to silicon photomultiplier." IEEE Transactions on Nuclear Science 61.5 (2014): 2678-2686.

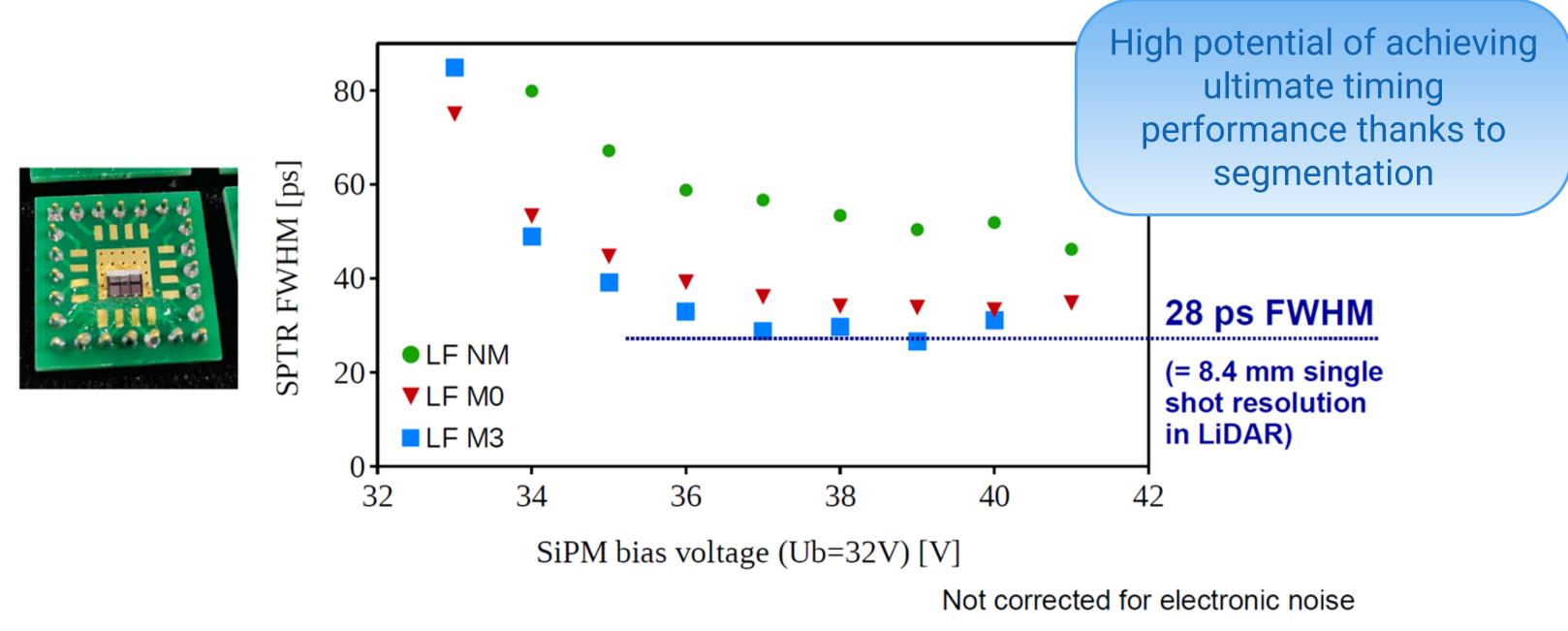
Example of segmented SiPM layout: a 3x3 mm2 active area is divided in 10 0.3x3 mm2 strip-SiPMs.





Segmentation SPTR of a 1x1 mm² CHK-HD with masking

A 1x1 mm² CHK-HD, with masking, was measured at Aachen (S. Gundacker) with high-frequency readout, achieving a remarkable Single Photon Time Resolution of 28 ps FWHM.







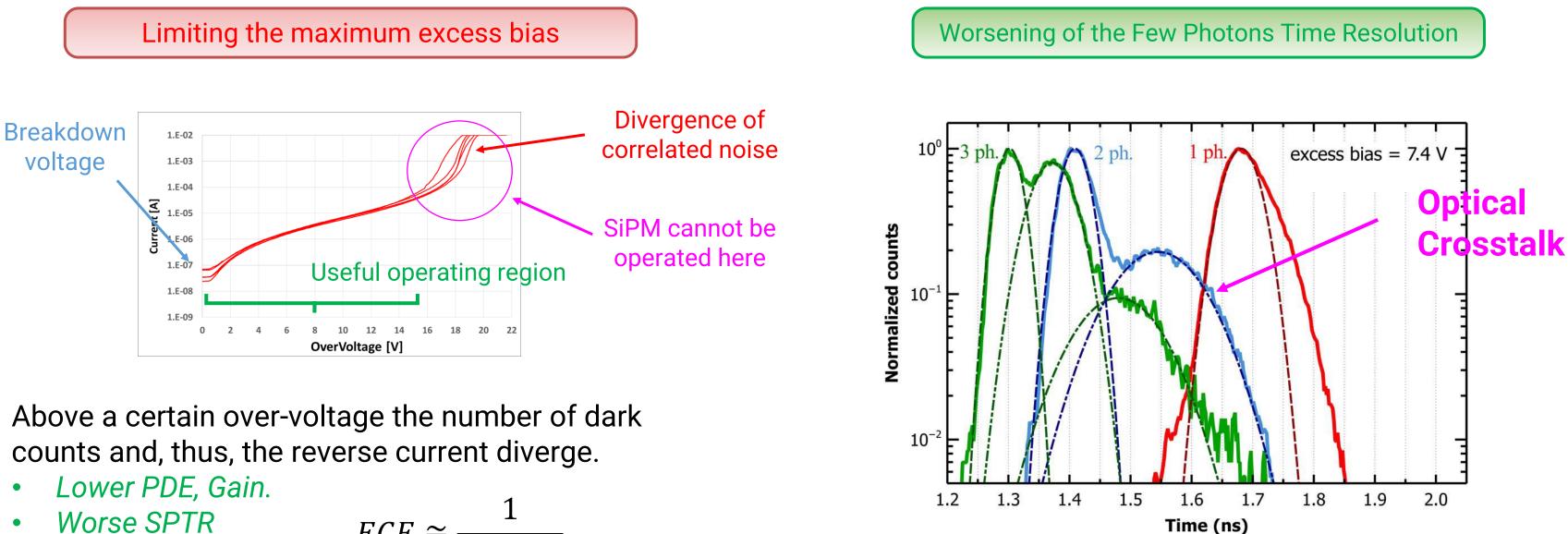
Reduction of Optical Crosstalk



Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

Optical Crosstalk Worsening of the performance of the detection system

Optical Crosstalk worsens the performance of the detection system both by *limiting the maximum excess bias* that can be applied to the SiPM and by worsening the photon time of arrival statistics.



$$ECF \cong \frac{1}{1 - P_{CN}}$$

Few-photon time resolution measured with Leading-edge discriminator Additional peaks are most likely generated by (delayed) correlated noise.

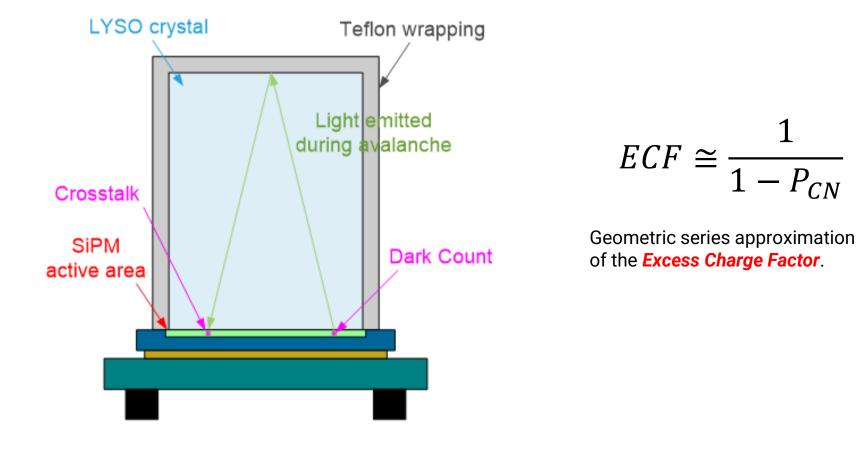
14



Geometric series approximation Acerbi, Fabio, et al. "Characterization of single-photon time of the Excess Charge Factor tus and perspectives of SiPMs at FB resolution: from single SPAD to silicon photomultiplier." IEEE 1 Transactions on Nuclear Science 61.5 (2014): 2678-2686.

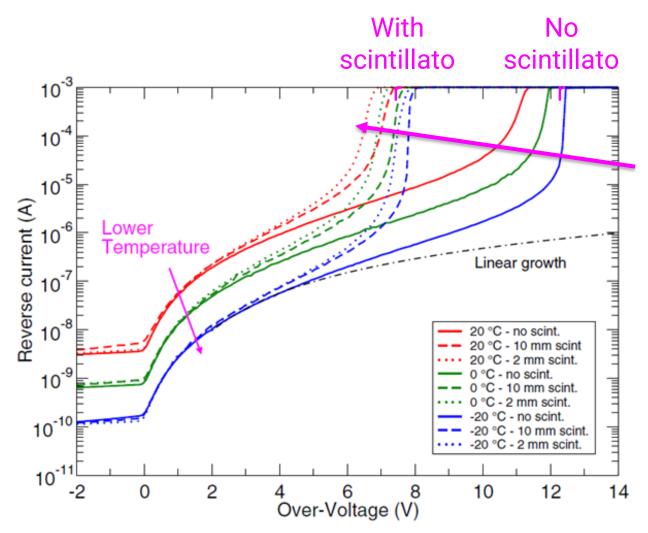
Optical crosstalk External Crosstalk

Optical crosstalk probability is enhanced by the presence of the scintillator: external crosstalk.



Mechanism of optical crosstalk probability enhancement because of the scintillator.

Gola, Alberto, et al. "SiPM optical crosstalk amplification due to scintillator crystal: effects on timing performance." Physics in Medicine & Biology 59.13 (2014): 3615.



Comparison of SiPM IV with different scintillator sizes placed on top of them, at different temperatures.

15

22/11/20

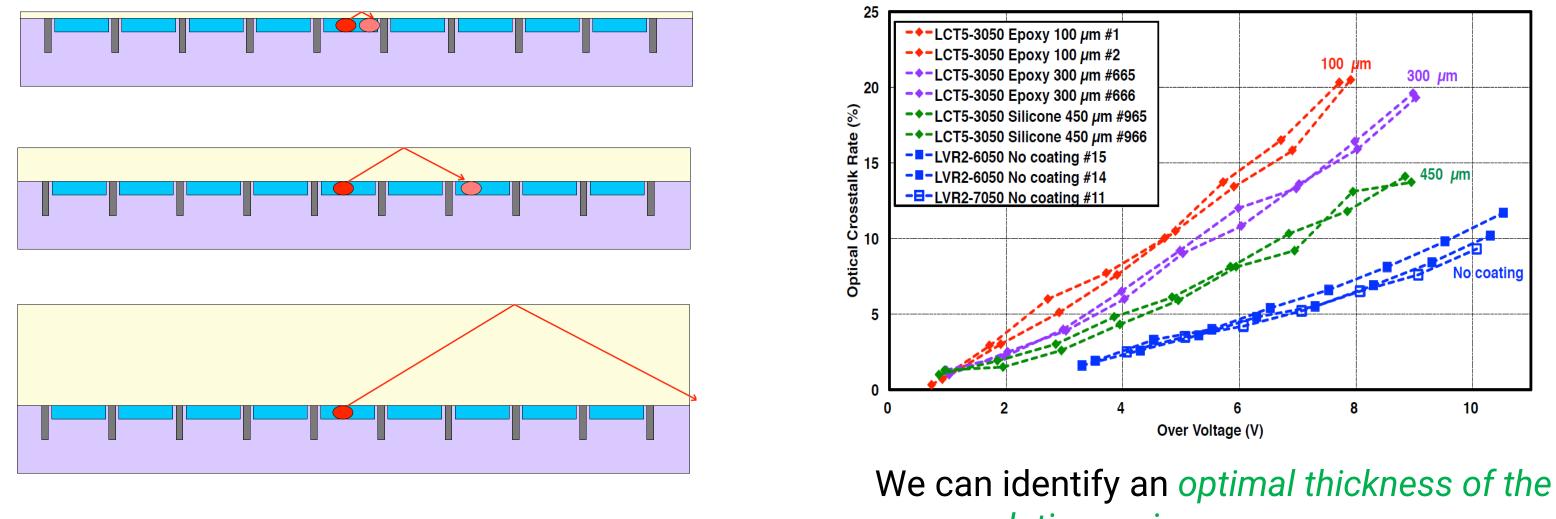


 $\overline{1 - P_{CN}}$

Optical crosstalk External Crosstalk and protective resin

The package geometry, in particular the resin thickness, has a significant effect on the optical crosstalk probability.

The effect was studied on Hamamatsu SiPMs and discussed in the ICASiPM conference.





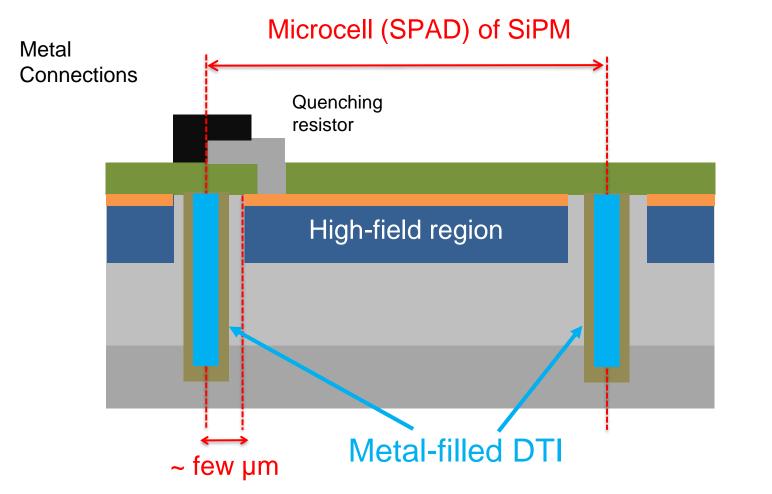
Suppressing Optical Cross Talk in Silicon Photomultiplier ICASiPM, JUN 11–15, 2018, Schwetzingen Germany

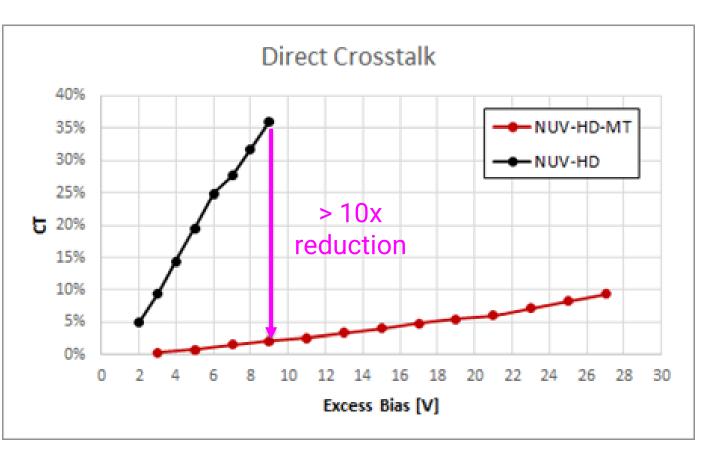
encapsulating resin

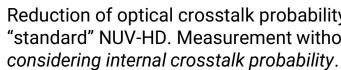
Reduction of optical crosstalk NUV-HD-MT development

Starting from the NUV-HD technology, FBK and Broadcom jointly developed the NUV-HD-MT technology, adding metal-filled DTI isolation to strongly suppress optical crosstalk.

Other changes: low electric field variant, layout optimized for timing.











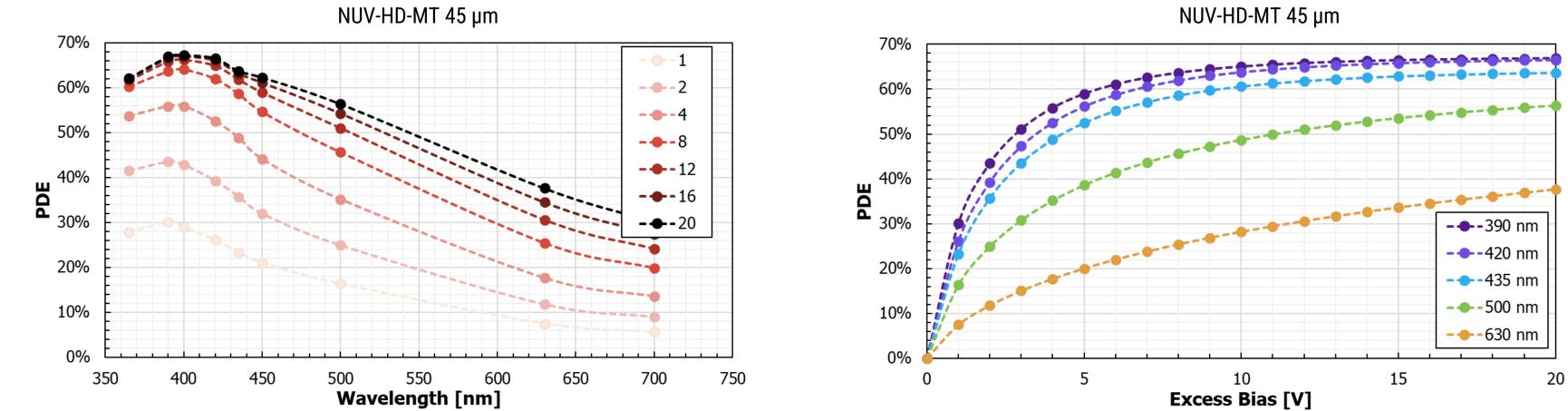
22/11/20

Reduction of optical crosstalk probability in NUV-HD-MT, compared to the "standard" NUV-HD. Measurement without encapsulation resin, i.e. only

Conceptual drawing of the NUV-HD-MT, with the addition of metal-filled Deep Trench Isolation.

Reduction of optical crosstalk NUV-HD-MT PDE

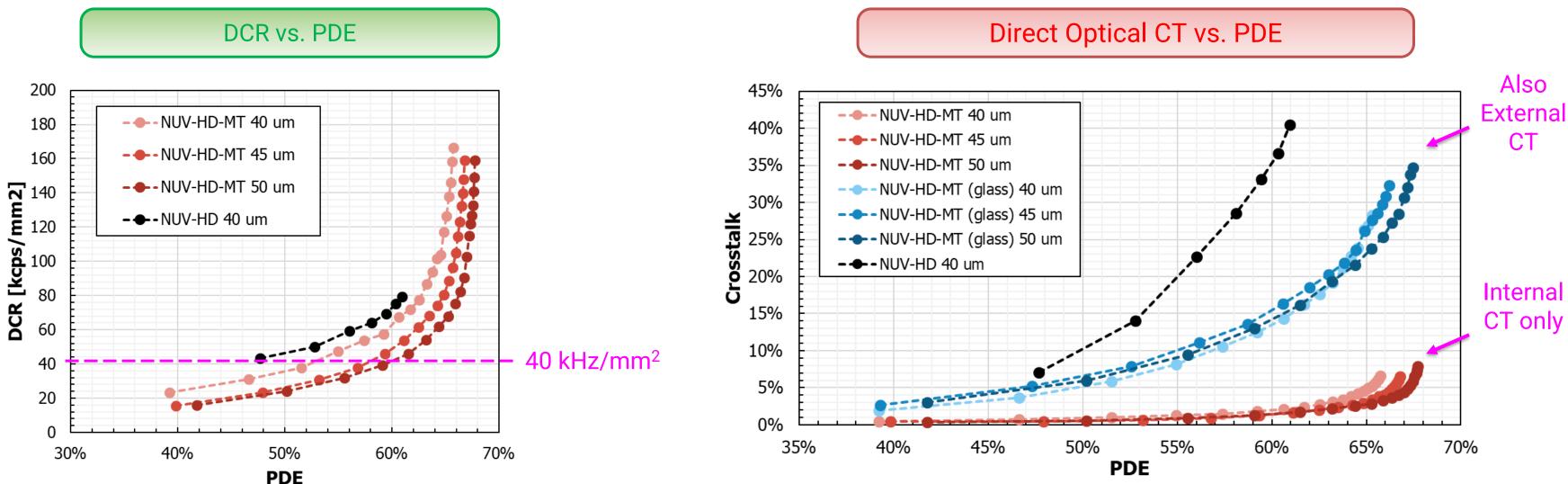
NUV-HD-MT is based on a p-on-n junction, thus peak PDE is around 390 – 420 nm. Thanks to the very high maximum excess bias, also PDE in the red (avalanche triggering by holes) approaches saturation.





Reduction of optical crosstalk NUV-HD-MT electro optical performance

NUV-HD-MT nuisance parameters are better represented and compared as a function of the PDE.



DCR vs. peak PDE (measured at 420 nm) for different cell sizes of the NUV-HD-MT technology.

DiCT vs. peak PDE (measured at 420 nm) for different cell sizes of the NUV-HD-MT technology, with and without protective glass on top of the SiPM (used for TSV)



19

Study of Radiation Hardness



Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

Radiation Hardness Motivation for R&D

Improving radiation hardness of SiPMs is one of the next frontiers of development at FBK for very important applications, both in big science experiments and in space.

> **Detectors for collider experiments:** from 10^{10} neg/cm^2 to > 10^{14} neg/cm^2





R&D approach:

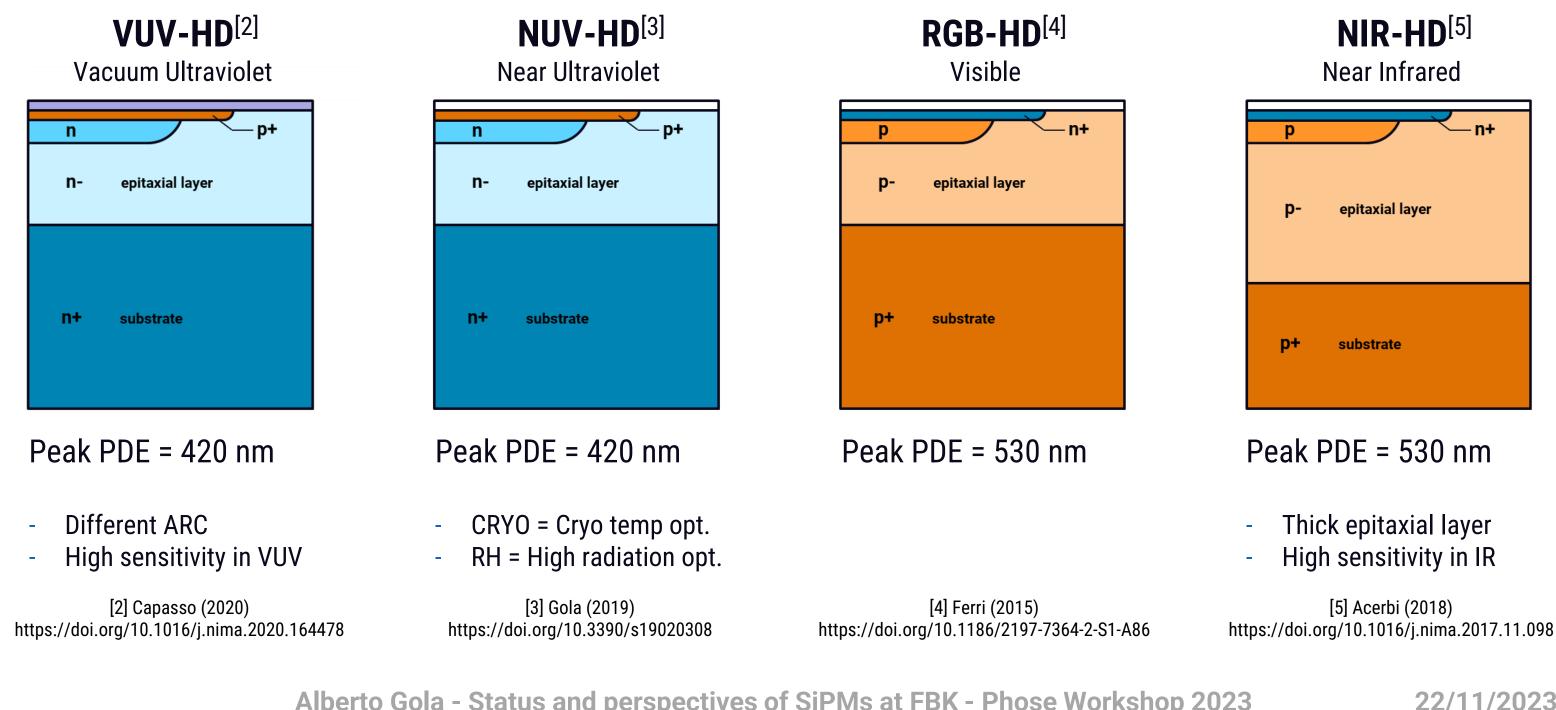
- Qualification of radiation tolerance of current SiPM technologies.
- Development of a highly customized SiPM technology for optimal performance after irradiation is likely needed.



Geostationary orbit space experiments: ~5·10¹⁰ neq/cm²

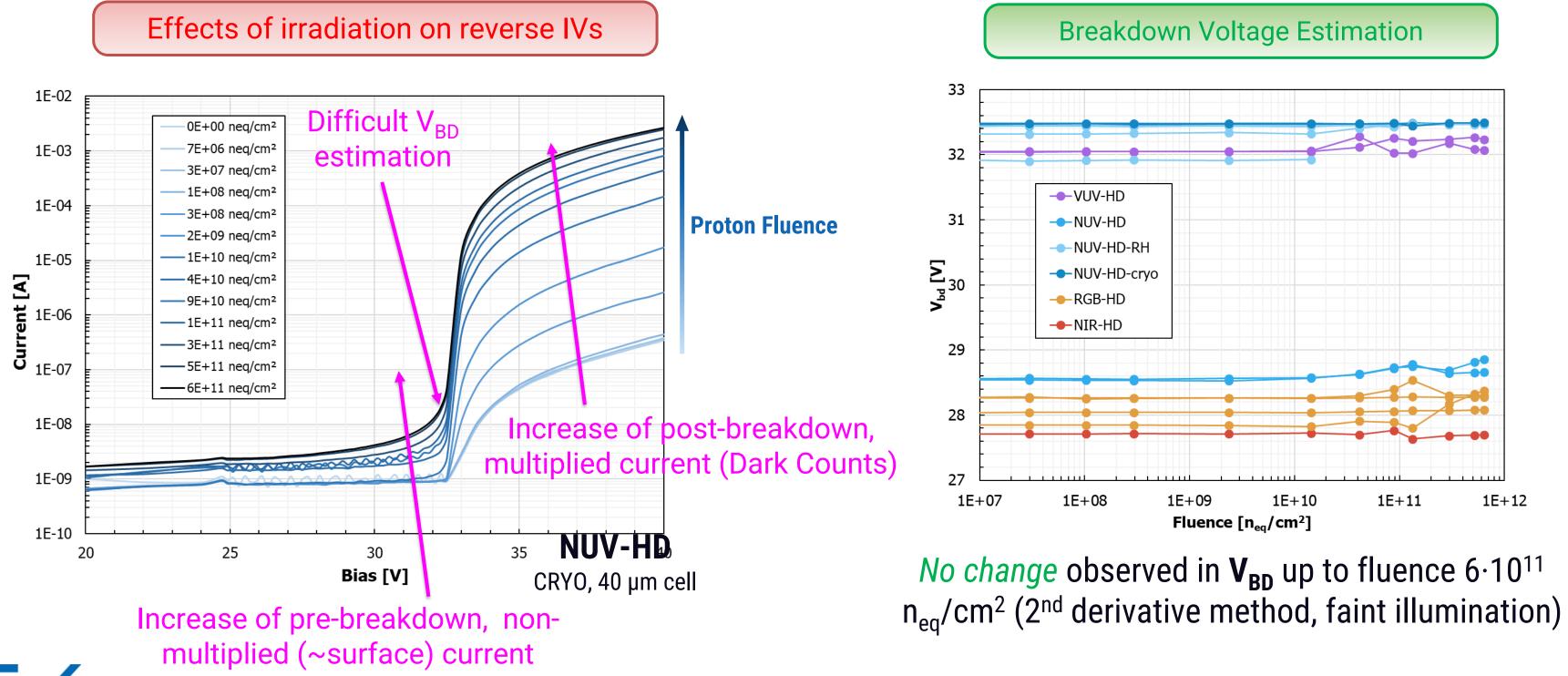
Test Beam 1 – Trento Proton Therapy Tested Technologies

We tested a relatively wide range of different customized SiPM technologies, fabricated in FBK internal R&D clean-room, looking for differences, general trends, etc..



Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

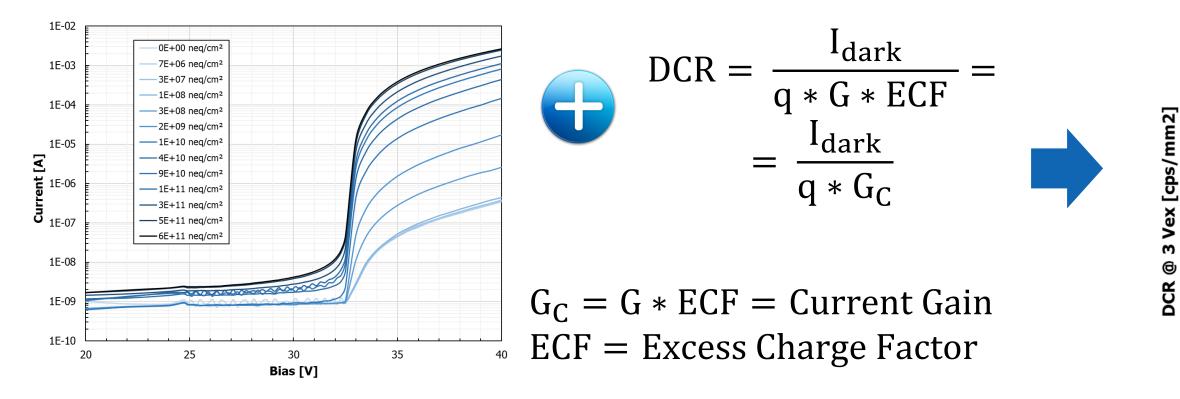
Test Beam 1 – Trento Proton Therapy Online IV measurements



Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

Test Beam 1 – Trento Proton Therapy Dark Count Rate Estimation from reverse IV

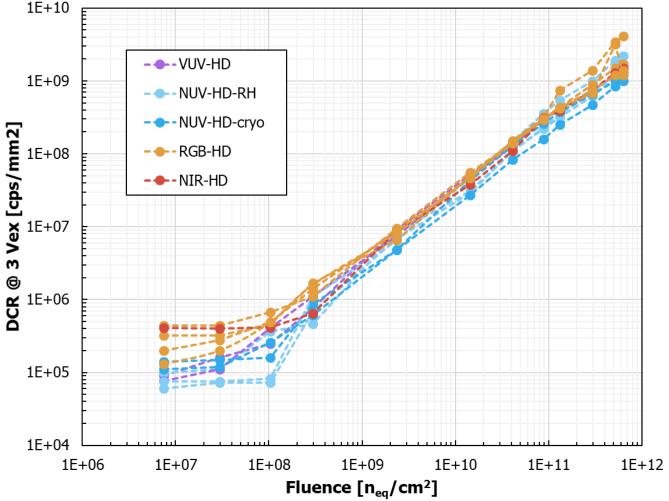
Comparison of radiation hardness of different SiPM technologies *cannot be done directly from their IVs* because they usually have different Gain and correlated noise (ECF).



Assumption: ECF and Gain do not change with irradiation (will be shown later)

DCR estimation for different FBK SiPM technologies.





Test Beam 1 – Trento Proton Therap Dark Count Rate vs. Fluence

There is little correlation between the DCR before and after *irradiation*:

- All technologies seem to "converge" towards similar values
- Knee between $10^7 \div 10^8 n_{eq}/cm^2$
- Independence of bulk damage from contaminants in the SiPM starting material?

DCR variation after irradiation is reduced:

- from ~1 OoM to < ~0.5 OoM
- Still worth investigating *differences between* technologies

Altamura, Anna Rita, et al. "Radiation damage on SiPMs for space applications." NIM-A 1045 (2023): 167488.



Acerbi, F., et al. "Characterization of radiation damages on Silicon photomultipliers by X-rays up to 100 kGy." NIM-A 1045 (2023): 167502. 1E+10

1E+09

1E+08

1E+08 **[cbs/mm2]** 1E+07

BO 1E+06

1E+05

1E+04

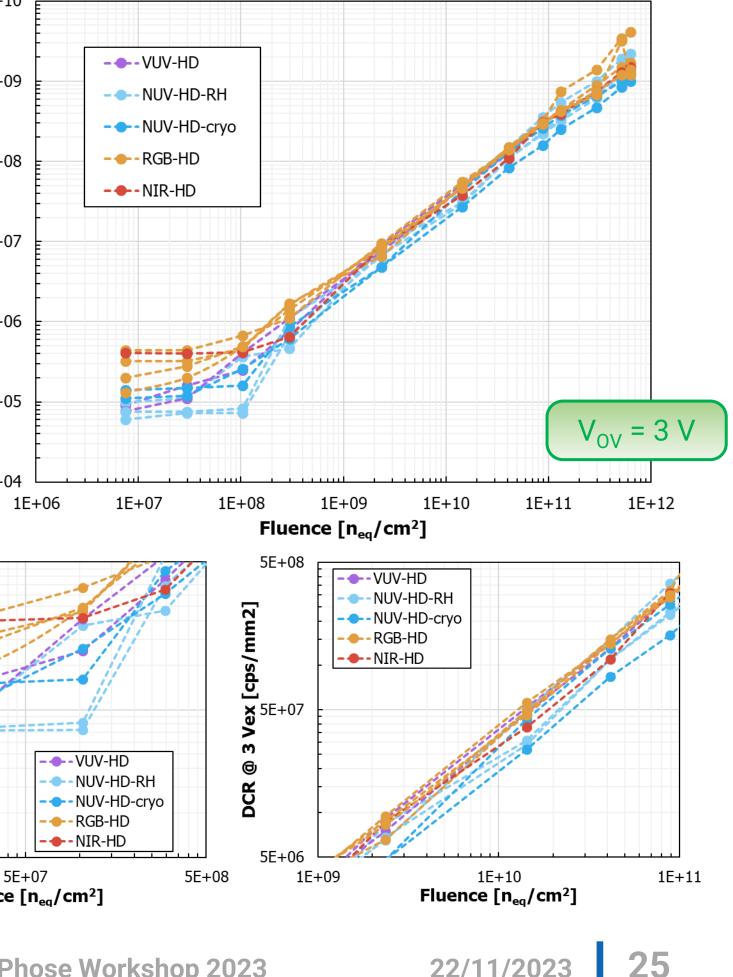
m 0

n2]

0

DCR

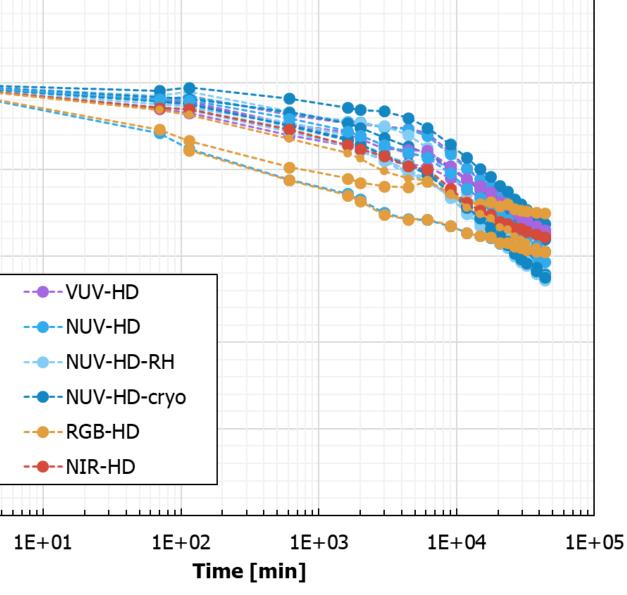
1E+04



Test Beam 1 – Trento Proton Therapy First Annealing studies

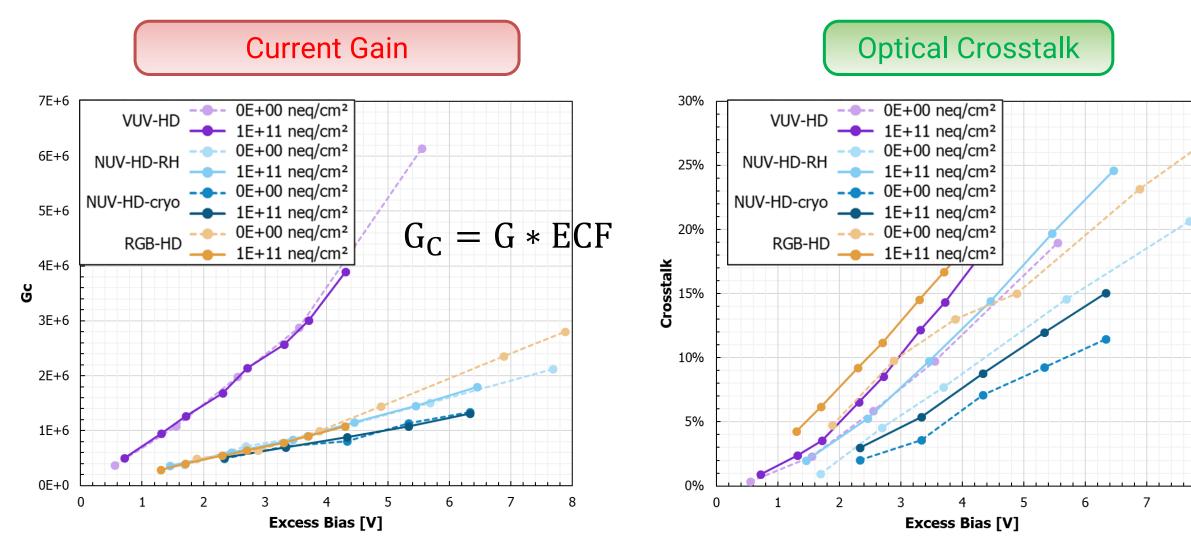
Annealing can be a *powerful mean of reducing DCR after irradiation* to recovers single-photon resolution.

- *Room temperature* annealing (20-25°C) on the highest dose only (6.4·10¹¹ 1 MeV n_{eq}/cm^2)
- *Two slopes observed*: knee point at around 1.5.10³ min(~1 day)
- Minor dependence on excess bias for a few samples.
- Higher annealing temperatures have demonstrated better annealing:
 - Factor > 10 after $1 \cdot 10^{11} n_{ea}/cm^2$ is reported in M. Calvi - https://doi.org/10.1016/j.nima.2019.01.013
 - See other presentations at the workshop (R. Preghenella)



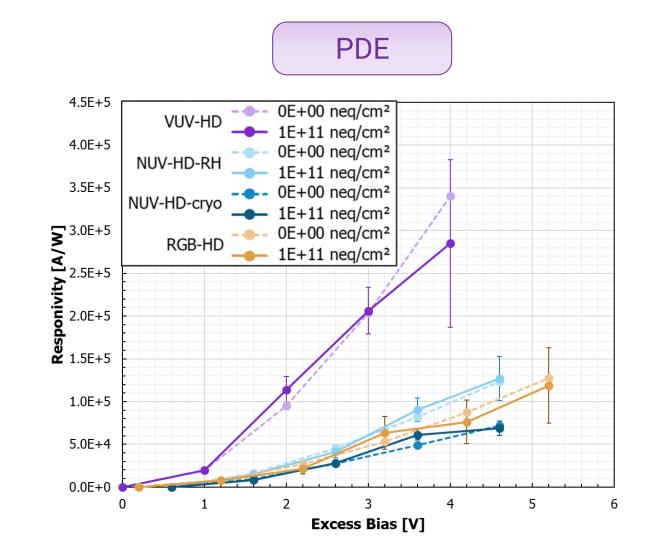
Test Beam 1 – Trento Proton Therapy Variation of the other SiPM parameters

Waveform analysis carried out at -40°C to reduce pile-up on the highest irradiation dose (1.10¹¹ n_{eq}/cm²). No relevant change of the other SiPM parameters, except for the DCR.



No change in Gain * ECF up to $1.10^{11} n_{eq}/cm^2$

Minor increase of CT is most likely an artifact caused by pile-up.

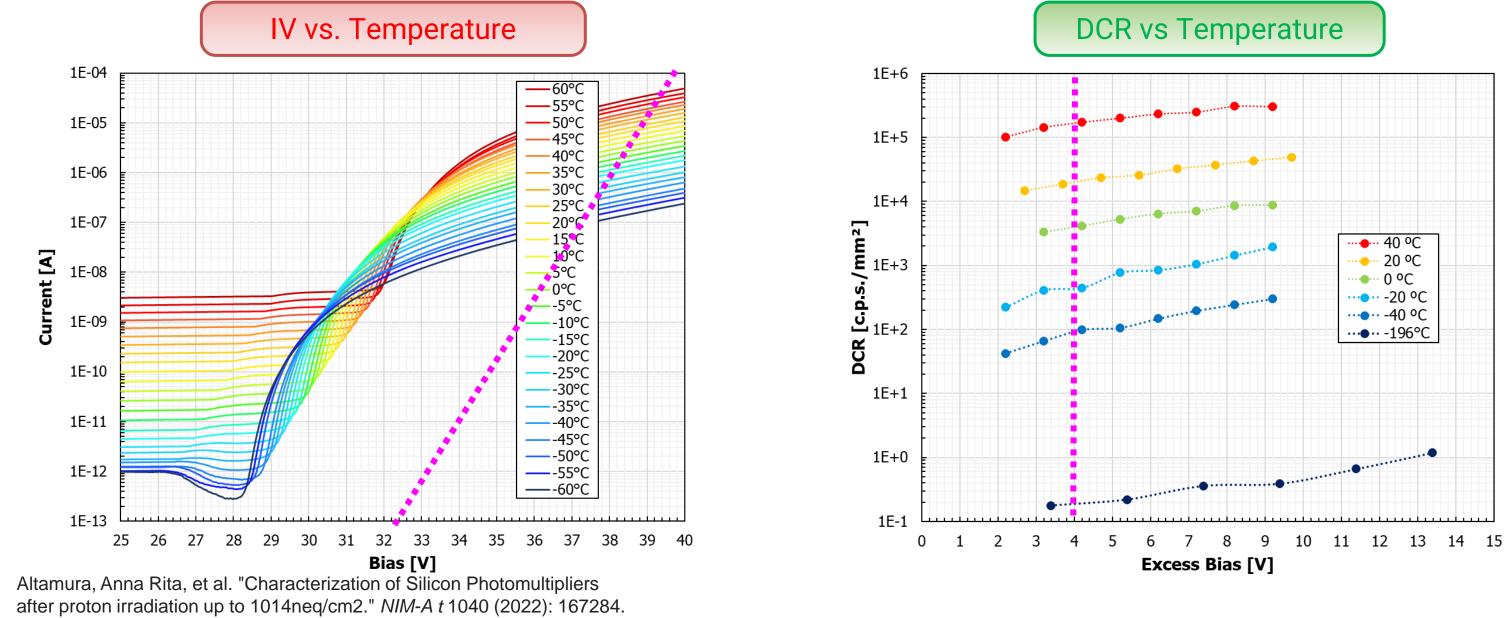


No change in PDE, measured as responsivity (loss of single photon resolution).

Test Beam 2 – LNS Catania DCR Analysis

Study of DCR after irradiation extended to cryogenic temperatures (preliminary).

- *IV* vs *Temperature*: $+60^{\circ}C \rightarrow -60^{\circ}C$
- DCR vs Temperature: +40°C \rightarrow -40°C, LN₂ (waveform analysis, when possible)



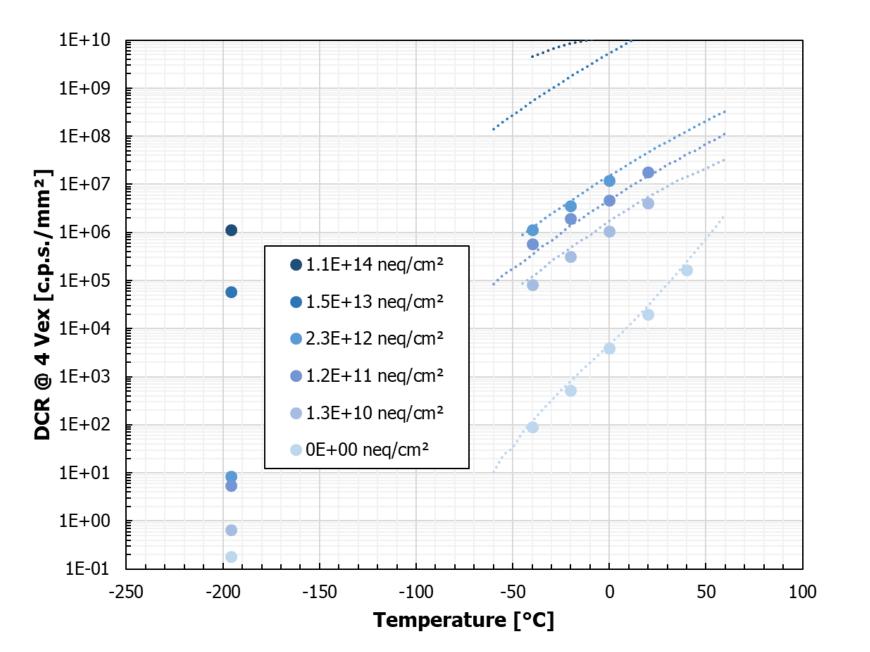
Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023



22/11/202

28

Test Beam 2 – LNS Catania DCR vs. Temperature and Dose



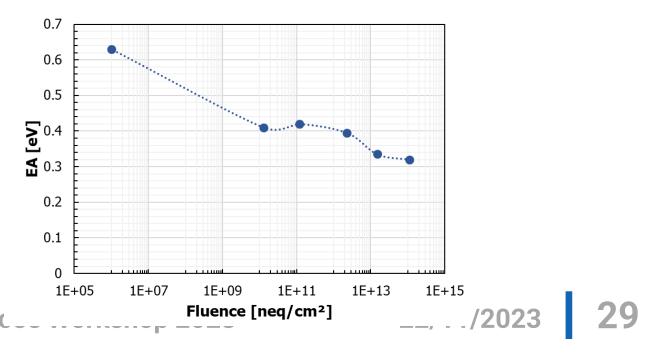
Reduction of DCR activation energy near room temperature after irradiation was observed. \rightarrow Cooling becomes less effective in reducing DCR.

Lines: DCR from IV *Dots*: DCR from waveform analysis

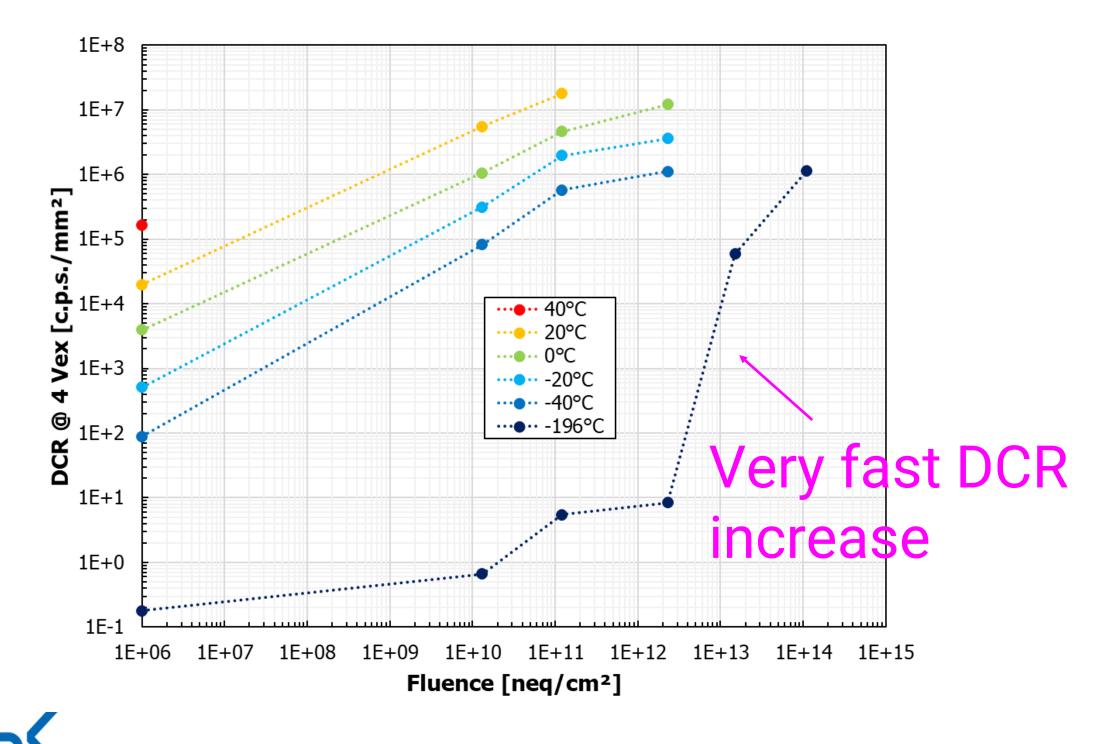
Alberto Gola - Status and perspectives of SiPMs at FBK - Phc



Fluence [n _{eq} /cm ²]	E _A [eV]
0E+00	0.63
1.3E+10	0.41
1.2E+11	0.42
2.3E+12	0.40
1.5E+13	0.34
1.1E+14	0.32



Test Beam 2 – LNS Catania DCR at LN after irradiation



Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

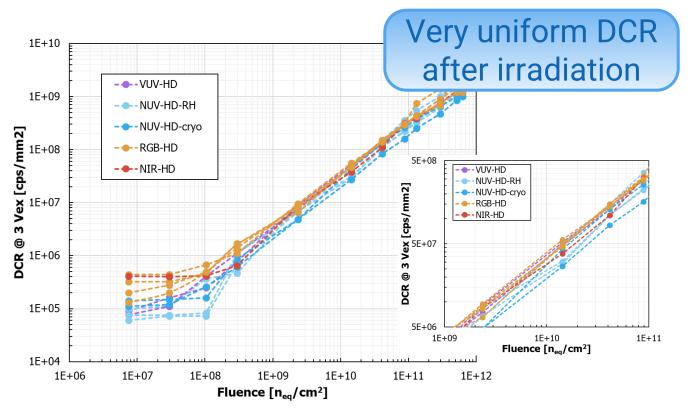


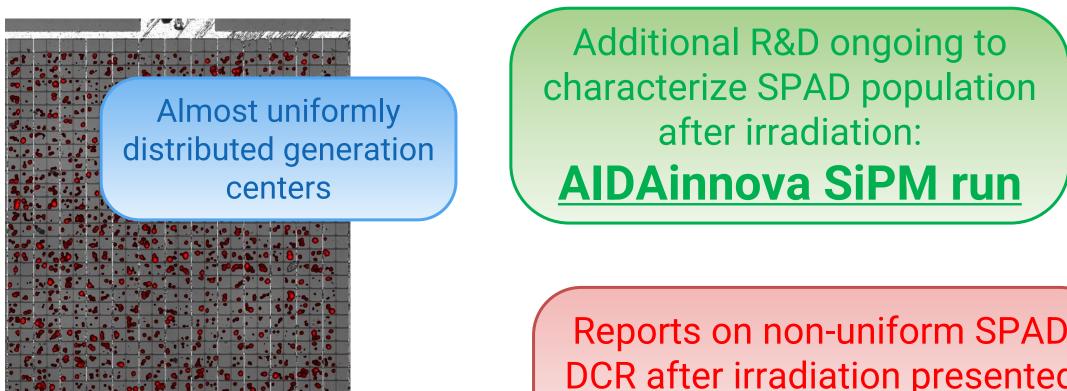
- Cooling is *extremely effective in* reducing DCR after irradiation up $to \sim 1.10^{12} n_{eq}/cm^2$
- Further investigations needed to understand what happens at the higher doses
- Worth checking different / new SiPM structures
- Check possible effect of annealing

Single SPAD switch-off **Effectiveness in reducing the DCR after irradiation**

Whether switching off "screamer" SPAD is effective to reduce DCR after irradiation depends on whether the increase of DCR is caused by:

- few, very rare, very "bad" bulk damage events, each one causing a large increase of the DCR \rightarrow single SPAD switch-off is useful.
- b. the sum of many, uniformly distributed, smaller events, each one responsible for smaller DCR increments \rightarrow single SPAD switch-off is not very useful.





DCR vs Fluence for different FBK technologies: all plots converge to similar values above approximately 1e8 n_{eq}/cm^2

Emission microscopy measurement on a NUV-HD SiPM irradiated at 1.10¹¹ n_{en}/cm², at 4V excess bias, showing almost uniform cell activation.

Reports on non-uniform SPAD DCR after irradiation presented at NSS2023 by L. Ratti

Light Concentration

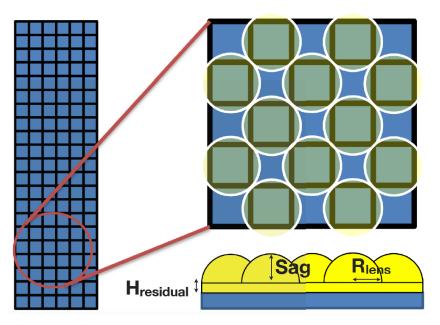


Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

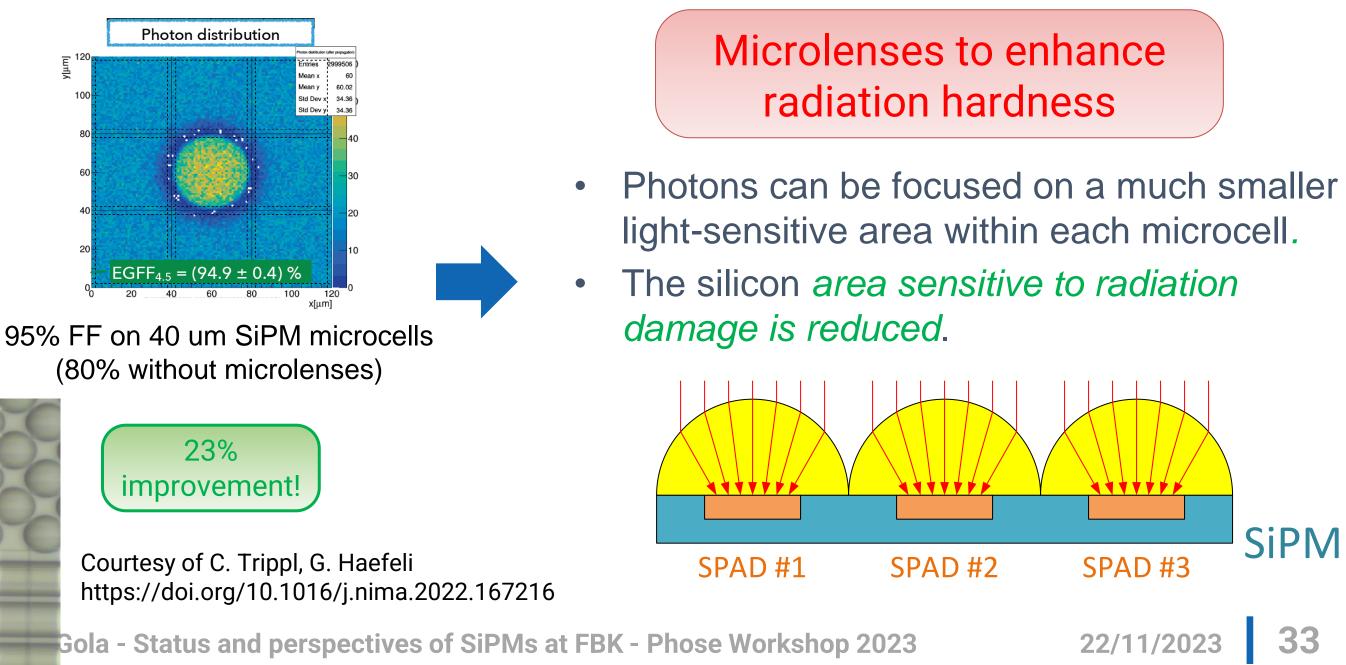
Light concentration Microlenses

Microlenses can be used to enhance the Fill Factor (FF) and thus the PDE of the SiPM microcells.

- Exploratory project between FBK and EPFL for LHCb SciFi tracker \rightarrow Sensitivity-enhanced SiPMs
- Effectiveness depends on the angular distribution of photons.



Proposed microlens geometry





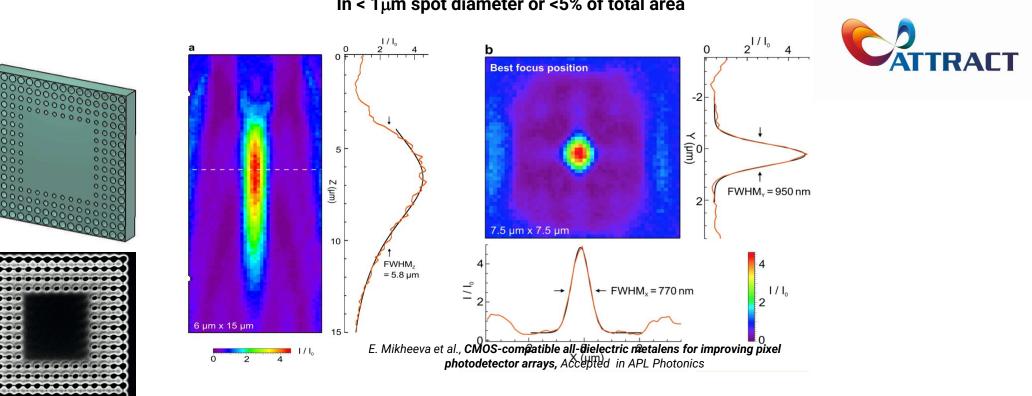
Light concentration **Metasurfaces and Metamaterials**



FBK investigated the possibility of using nanophotonics to enhance SiPM performance in the context of the PHOTOQUANT ATTRACT project.

Metalens-based light concentrators can work similarly to microlenses to enhance SiPM radiation hardness.

Advantages: rad-hard metalens material (TBC), compatibility with CMOS planar processing.



93% of incident light concentrated In < 1 μ m spot diameter or <5% of total area

Experimental metalens designed and fabricated $4x4\mu m Nb_2O_5$ metalens with refractive index gradient introduced by holes of varying diameter, (joint ATTRACT project CERN, FBK, Institut Fresnel.)



Mikheeva et al., CMOS-compatible all-dielectric metalens for improving pixel photodetector arrays, Accepted in APL Photonics Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023





Next generation developments: 2.5D and 3D integration

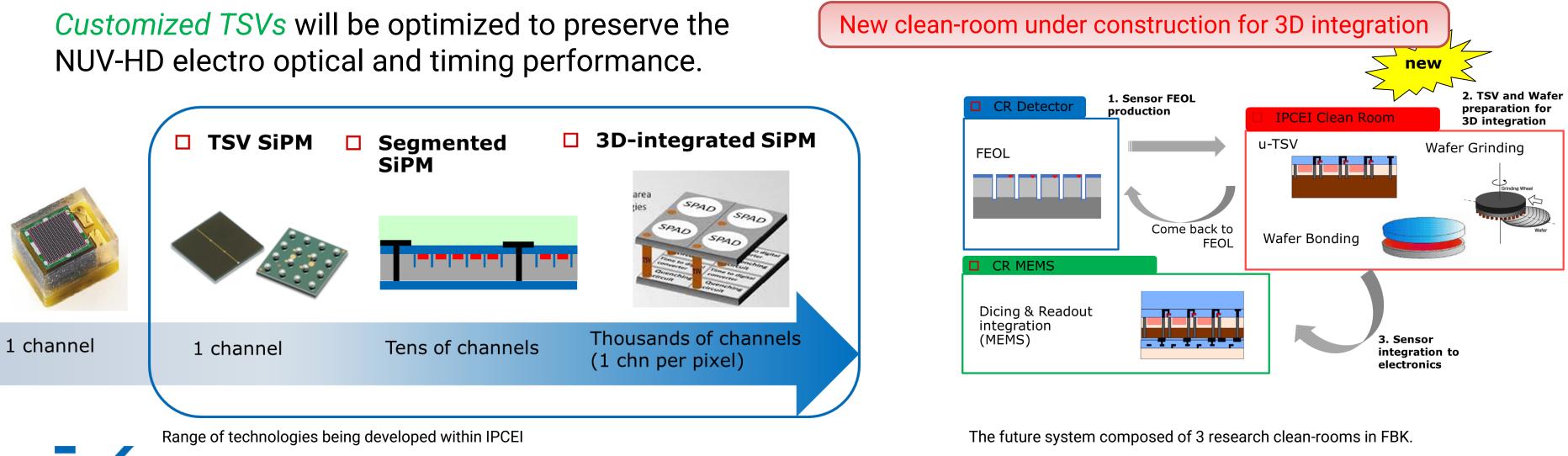


Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

2.5D and 3D Integration FBK IPCEI clean-room upgrade

FBK is part of the *IPCEI on microelectronics* project (Important Project of Common European Interest - €1.75 billion total public support, 12 M€ to FBK).

The goal for FBK is upgrading its optical sensors technologies, by *developing TSVs, micro-TSV and Backside Illuminated SiPMs*. This will allow high-density interconnections to the front-end and high-segmentation.



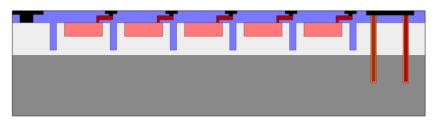


36

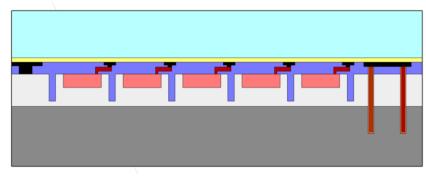
2.5D and 3D Integration TSV – via mid: process flow

In the via-mid process, the TSV is formed during the fabrication of the SiPM, modifying its process flow.

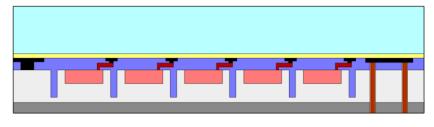
SiPM fabrication + TSV formation



Edge Trimming + BONDING



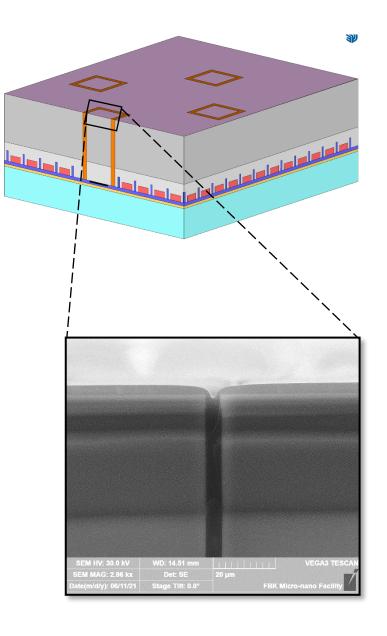
THINNING



- **NO-DEBONDING** DEBONDING Thickness at least 150 um Thickness 10-50 um **Glass-less TSV** Standard TSV concept **microTSV** 500 um SiPM pitch < 50 um SPAD pitch
- **Contacts formation**

Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023





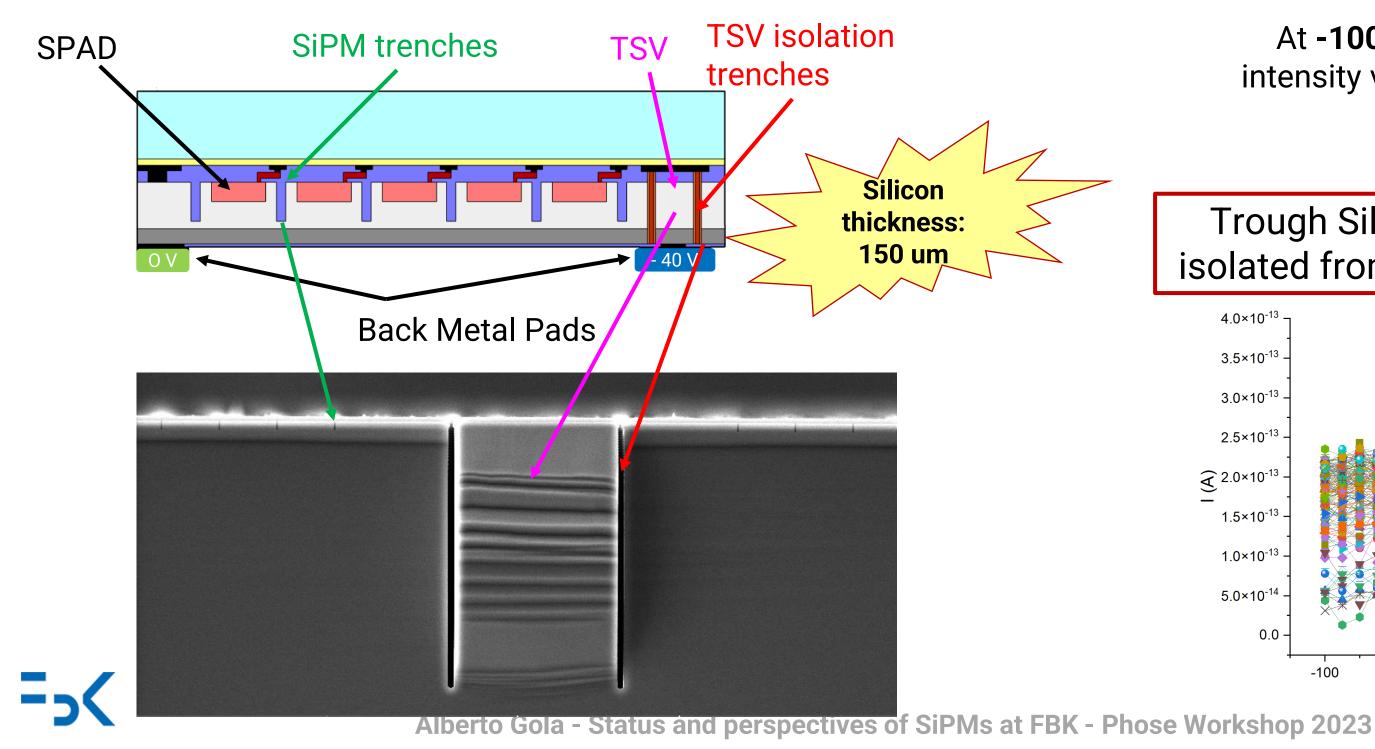






2.5D and 3D Integration TSV – via mid: first results

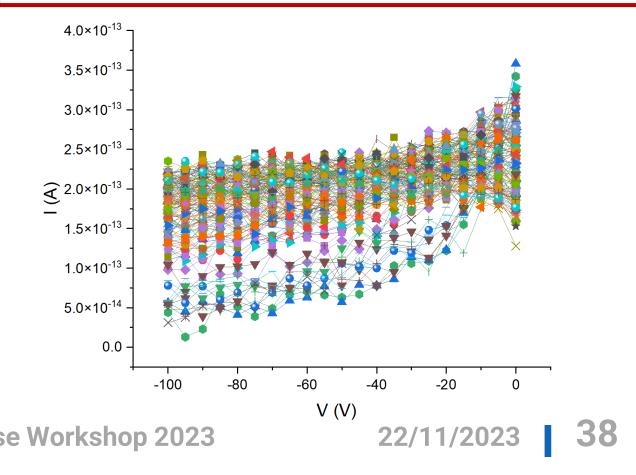
Preliminary results on TSV via-mid development, with partial SiPM process, to check isolation and continuity (no Geiger-mode multiplication).





At **-100 V** of bias applied the intensity varies from 30 to 200 fA

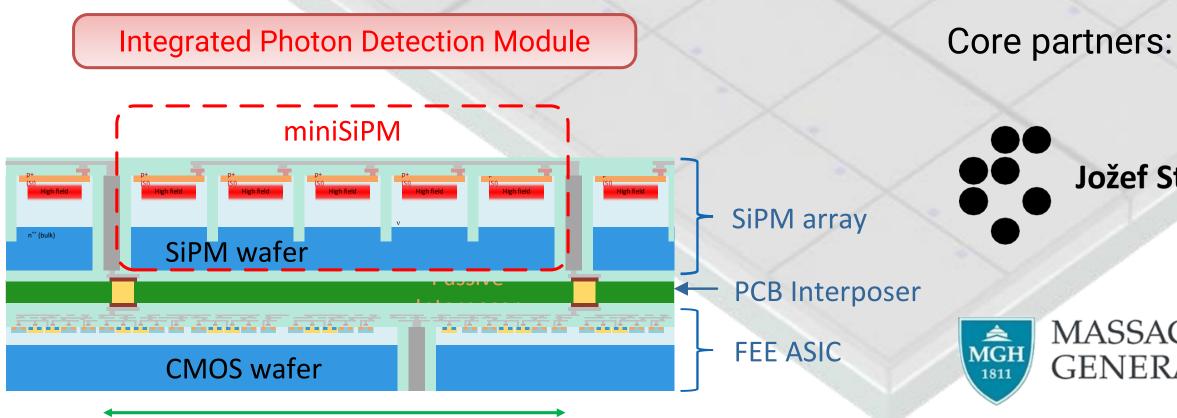
Trough Silicon Vias – Via Mid are isolated from the bulk silicon contact



2.5D and 3D Integration 2.5D integrated SiPM tile

In the short and medium term, medium density interconnection seems the sweet spot to obtain excellent performance (e.g. timing) on large photosensitive areas while not increasing complexity and cost too much.

We propose a Photon Detection Module (PDM) in which SiPMs with TSVs down to 1 mm pitch are connected to the readout ASIC on the opposite side of a passive interposer, in a 2.5D integration scheme.



1 - 3 mm interconnection pitch

Hybrid SiPM module being developed for ultimate timing performance in ToF-PET

Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

Jožef Stefan Institute



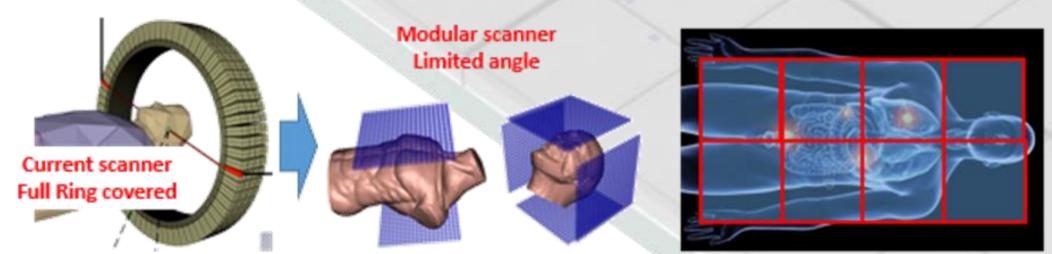
MASSACHUSETTS GENERAL HOSPITAL



2.5D and 3D Integration 2.5D integrated SiPM tile for timing

The 2.5D integrated PDM (50x50 mm²) will be the basis of a 30x30 cm² ToF-PET panel, which will be used to build limited-angle ToF-PET systems, for brain PET, Cardiac PET and full-body scanners.

We expect very good timing performance, supported by preliminary measurements achieved with NUV-HD SiPMs coupled to FastIC ASIC.



Application of the PDM to build large panes used in new, limted-angle PET applications: Brain Pet, Cardiac PET, while-body PFT

Conceptual drawing of the PDM under development

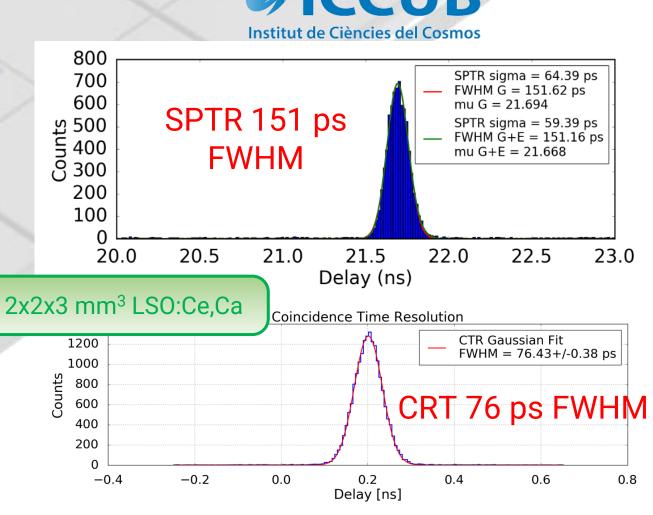
Alberto Gola - Status and perspectives of SiPMs at FBK - Phos **Power consumption:** 3 mW / channel

50 mm







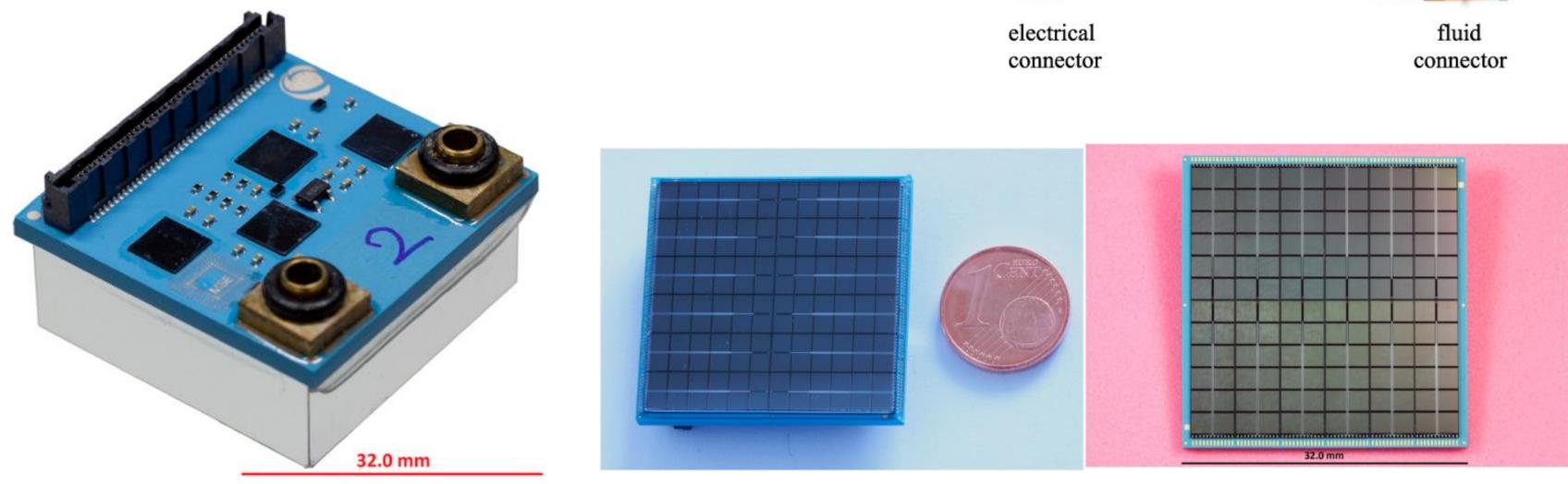


SPTR and CRT measured at FBK NUV-HD-SiPMs read by the FastIC ASIC developed by ICCUB. **Sensor:** NUV-HD-LFv2 SiPMs, 3x3 mm² **Scintillator:** 2x2x3 mm³ LSO:Ce,Ca 40

2.5D and 3D Integration **Example of integrated cooling**

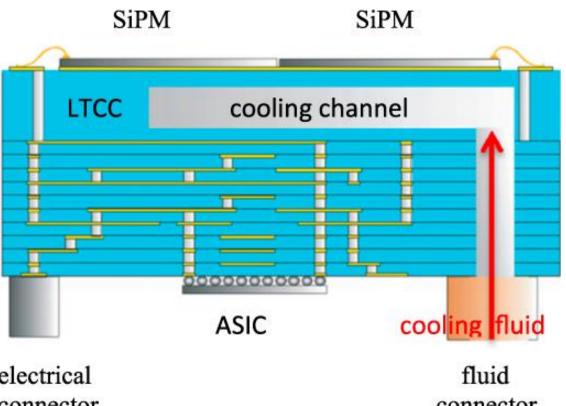
2.5D integration also allows to build *micro cooling channels* integrated inside the passive interposer.

Demonstrated in 2014 within SUBLIMA project (ToF-PET), using LTCC, FBK sensors and wire bonding.



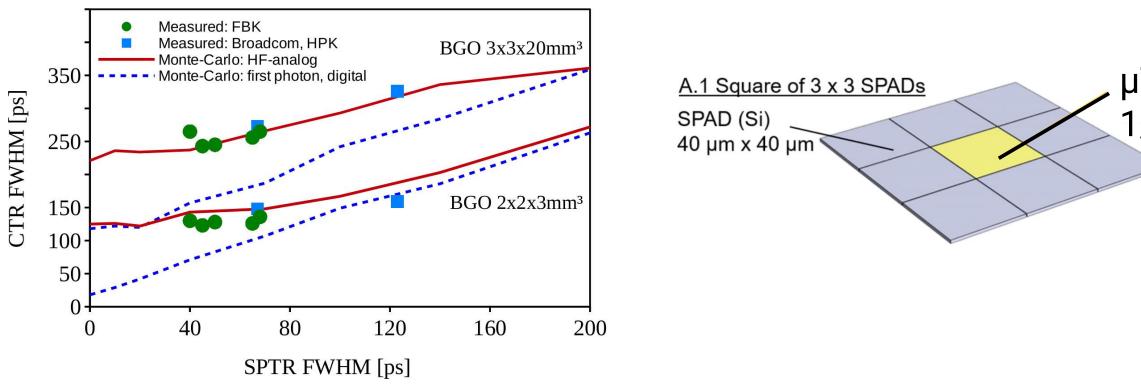


Dohle, Rainer, et al. "LTCC-based highly integrated SiPM module with integrated liquid cooling channels for high resolution molecular imaging." Journal of Microelectronics and Electronic Packaging 15.2 (2018): 86-94. Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023



2.5D and 3D Integration **High-density integration: DIGILOG**

FBK is also investigating higher density interconnections to approach the dSiPM performance without the complexity of single-SPAD access.



S. Gundacker, et al., A. Gola, E. Charbon, V. Schultz NSS 2023 S. Gundacker, et al., to be published 2023

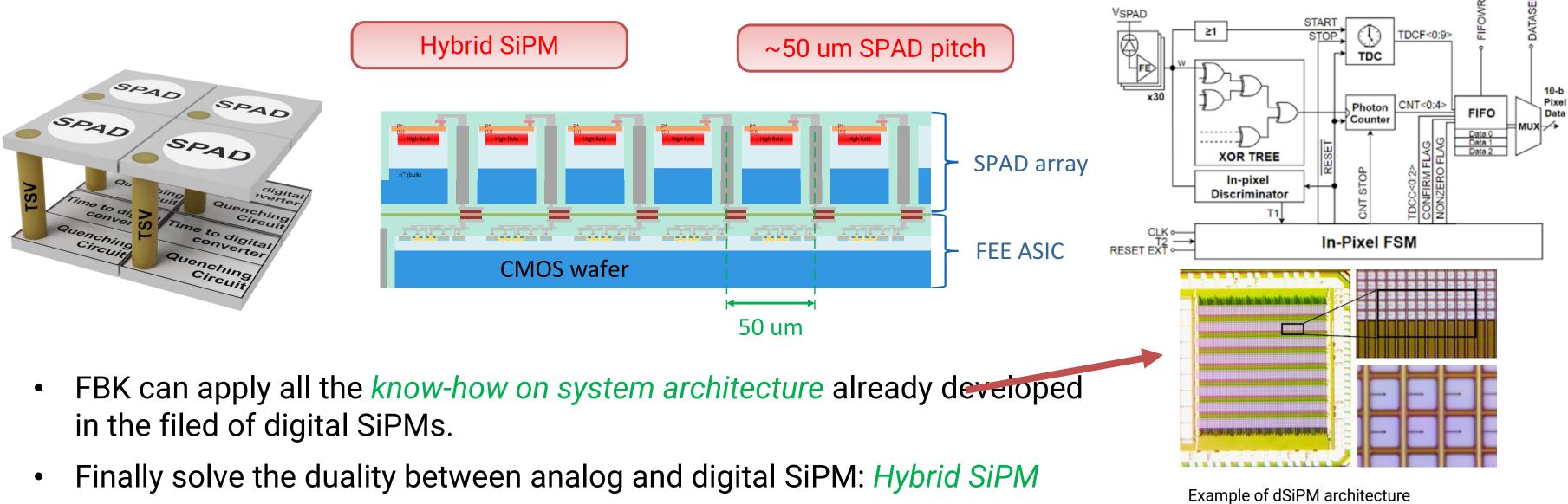
- μTSV 1/9 of area
- µSiPMs with **µTSVs**
- µASICs with in situ TDCs
- Embedded ANNs

22/11/20

 Distributed computing

2.5D and 3D Integration Full 3D integration with micro TSVs: Hybrid SiPM

FBK is investigating the potential of microTSVs to achieve single cell connection. While complexity of the system increases, it might provide *ultimate timing performance*.

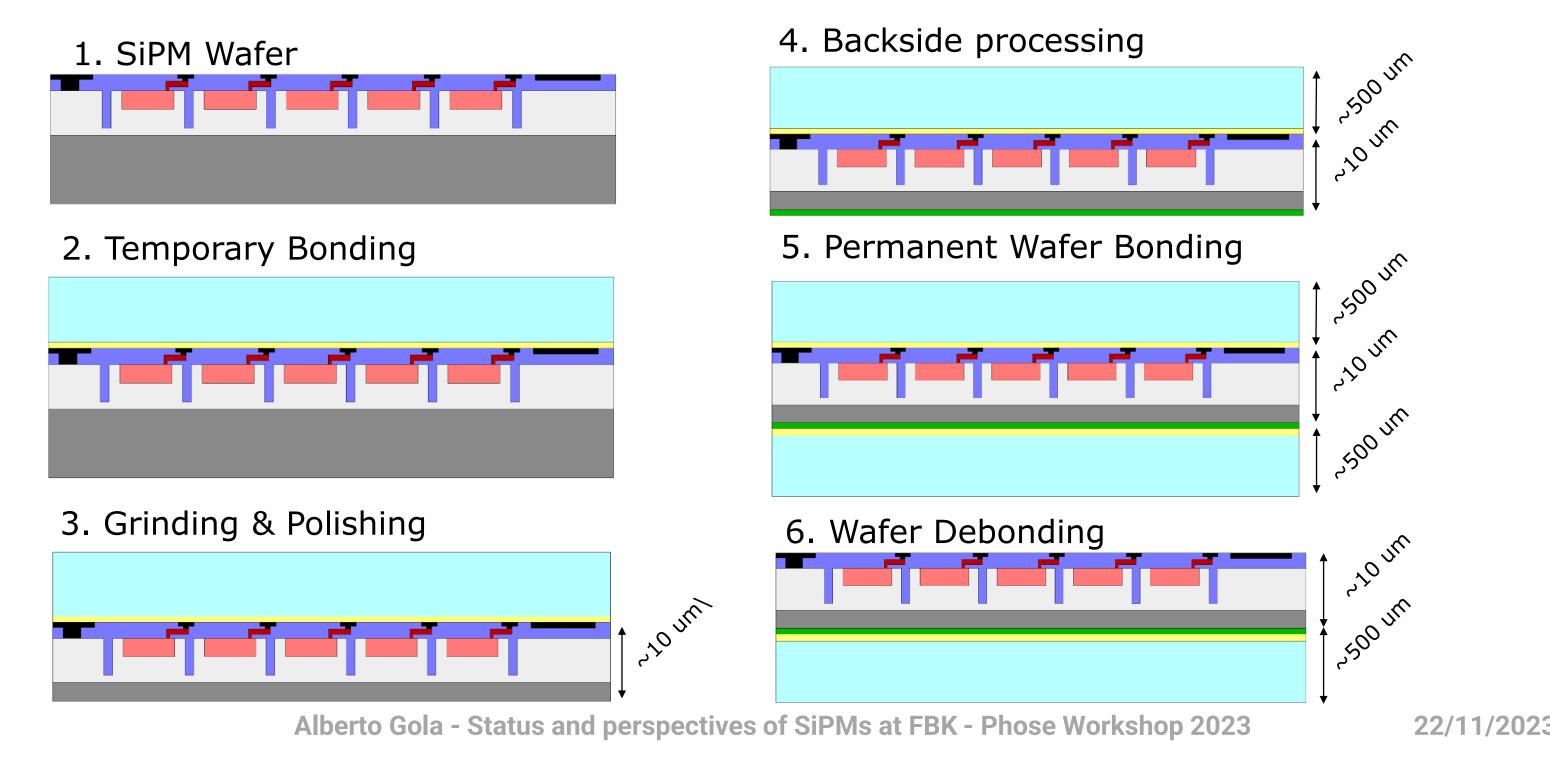


- concept.

developed at FBK (SBAM project)

2.5D and 3D Integration **Backside Illuminated SiPMs: process flow**

BSI development started on NIR-sensitive SiPMs \rightarrow no need to create a new entrance window on the backside with high efficiency in the NUV.



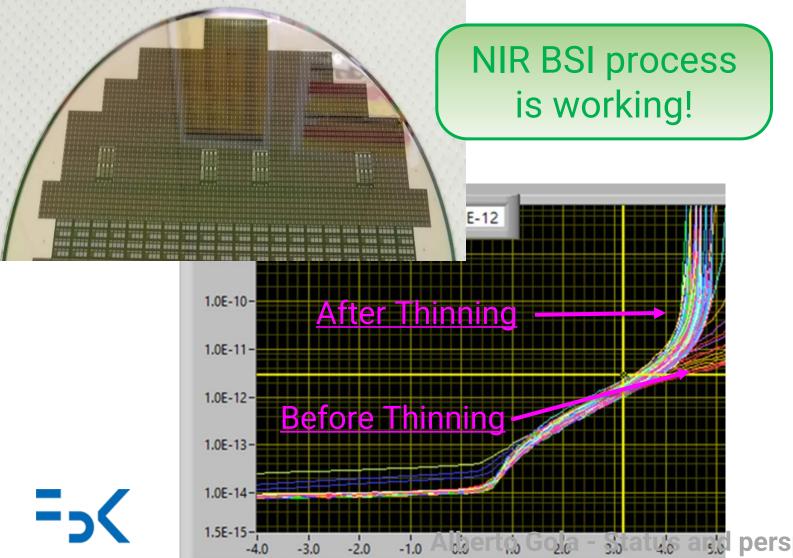


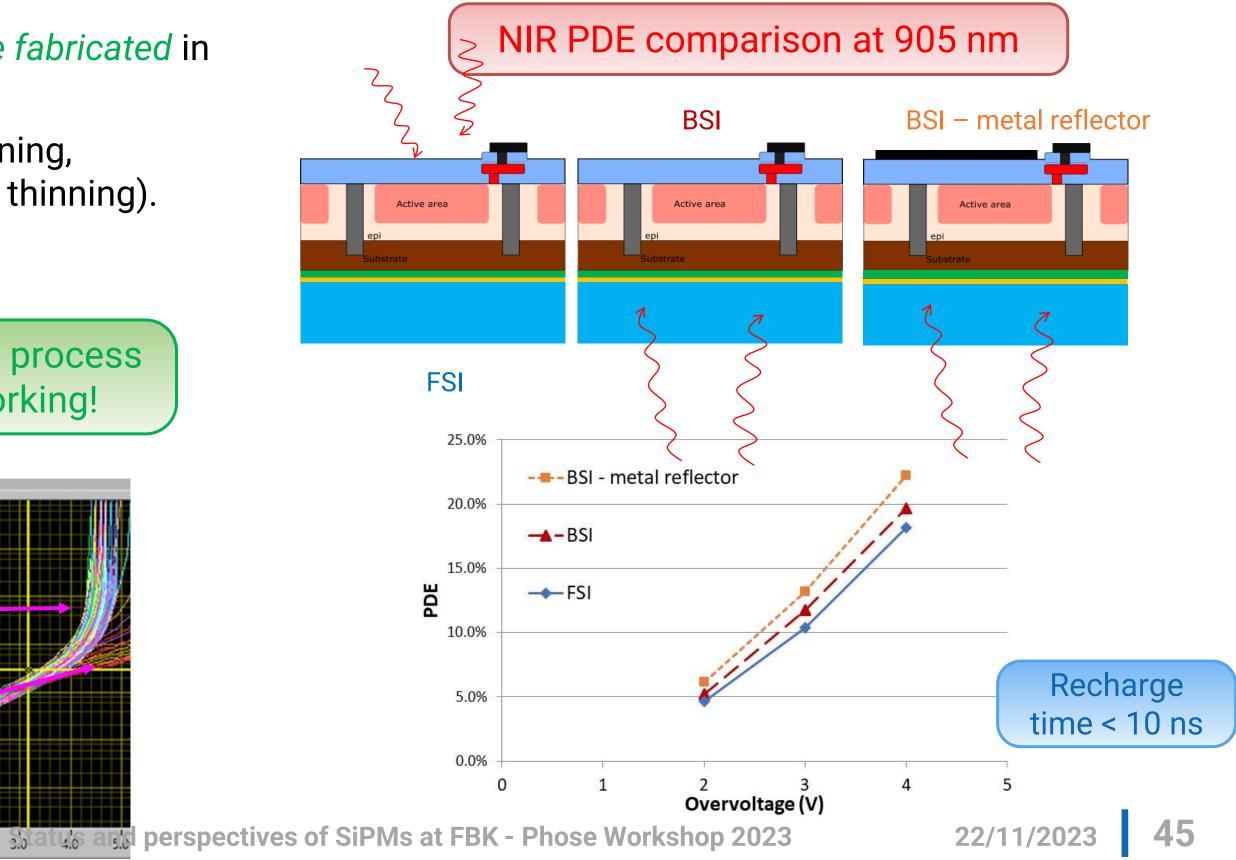
2.5D and 3D Integration **BSI NIR SiPMs: first results**

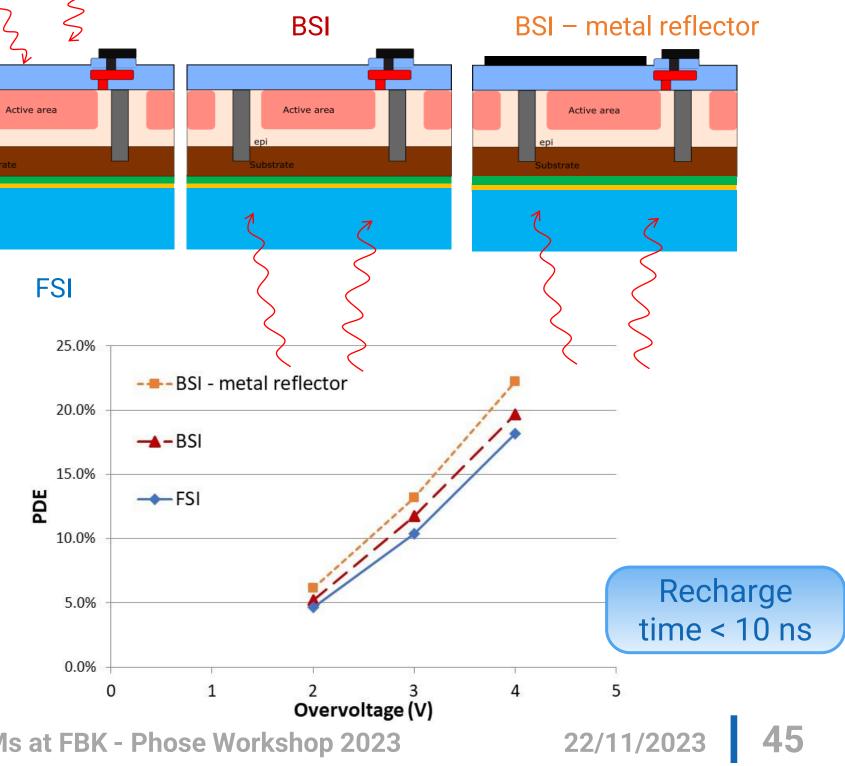
The first NIR-sensitive BSI wafers were fabricated in FBK clean room (1x1 mm² devices).

Minor differences in the IVs after thinning, compared to the FSI devices (without thinning).

Ultrathin substrate (~ 10 um)









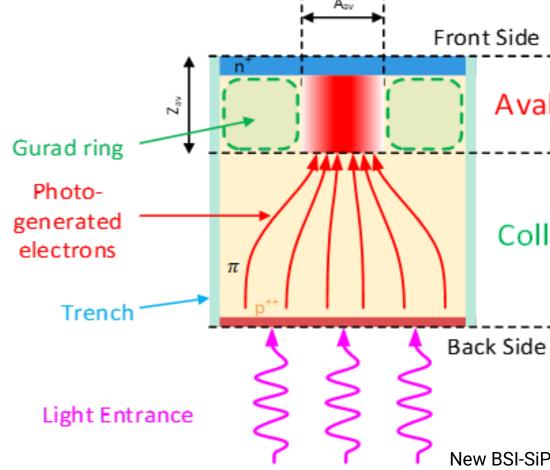
2.5D and 3D Integration **Next-generation development: Backside Illuminated SiPMs**

The next-generation of developments, currently being investigated at FBK, is building a *backside-illuminated*, *NUV-sensitive SiPM*. Several technological challenges should be overcome.

Clear separation between charge collection and multiplication regions.

Potential Advantages:

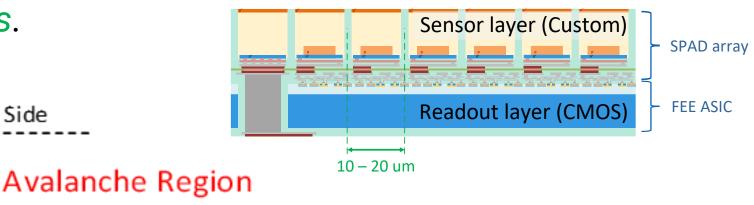
- <u>Up to 100% FF</u> even with small cell pitch
- Ultimate Interconnection density: < 15 um
- High speed and dynamic range
- Low gain and external crosstalk
- (Uniform) entrance window on the backside, ideal for enhanced optical stack (VUV sensitivity, nanophotonics)
- Local electronics: ultra fast and possibly low-power.



Radiation hardness:

- The SiPM area sensitive to radiation damage, is much smaller than the light sensitive area
- **Assumption**: the main source of DCR is field-enhanced generation (or tunneling).





Collection Region

Development Risks:

- Charge collection time jitter
- Low Gain \rightarrow SPTR?
- Effectiveness of the new entrance window

New BSI-SiPM structure

Thank you!



Alberto Gola - Status and perspectives of SiPMs at FBK - Phose Workshop 2023

Thanks to all the members of the team working on custom SiPM technology at FBK:

- Fabio Acerbi
- Andrea Ficorella
- Oscar Marti Villareal
- Stefano Merzi
- Elena Moretti
- Giovanni Palù
- Laura Parellada Monreal
- Giovanni Paternoster
- Michele Penna
- Maria Ruzzarin
- Tiziano Stedile
- Nicola Zorzi